

# Agilent E8267D PSG Vector Signal Generator

### **Data Sheet**



The Agilent E8267D is a fully synthesized signal generator with high output power, low phase noise, and I/Q modulation capability.

Specifications apply over a 0 to 55 °C range, unless otherwise stated, and apply after a 45 minute warm-up time. With vector modulation on, specifications apply after executing I/Q calibration with the instrument maintained within  $\pm 5$  °C of the calibration temperature unless otherwise stated. Supplemental characteristics, denoted as typical, nominal, or measured, provide additional (non-warranted) information at 25 °C, which may be useful in the application of the product.

Unless otherwise noted, this data sheet applies to units with serial numbers ending with 50420000 or greater.

### **Definitions**

**Specifications (spec):** Represents warranted performance for instruments with a current calibration.

**Typical (typ):** Represents characteristic performance which is non-warranted. Describes performance that will be met by a minimum of 80% of all products.

**Nominal (nom):** Represents characteristic performance which is non-warranted. Represents the value of a parameter that is most likely to occur; the expected mean or mode of all instruments at room temperature (approximately 25 °C).

**Measured:** Represents characteristic performance which is non-warranted. Represents the value of a parameter measured on an instrument during design verification.



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### **Specifications**

Frequency			
Range	Specified range	Tunable range	
Option 520	250 kHz to 20 GHz	100 kHz to 20 GHz	
Option 532	250 kHz to 31.8 GHz	100 kHz to 31.8 GHz	
Option 544	250 kHz to 44 GHz	100 kHz to 44 GHz	
Resolution			
CW	0.001 Hz		
All sweep modes <sup>1</sup>	0.01 Hz		
Switching speed <sup>2, 3, 4</sup>	Standard	Opt UNX	Opt UNY
I/Q modulation off	< 16 ms (typ)	< 16 ms (typ)	< 26 ms (typ)
I/Q modulation on	< 24 ms (typ)	< 24 ms (typ)	< 34 ms (typ)
Phase offset	Adjustable in nominal 0.1° increments		
Frequency bands	Frequency range	N <sup>5</sup>	
1	250 kHz to 250 MHz	1/8	
2	> 250 to 500 MHz	1/16	
3	> 500 MHz to 1 GHz	1/8	
4	> 1 to 2 GHz	1/4	
5	> 2 to 3.2 GHz	1/2	
6	> 3.2 to 10 GHz	1	
7	> 10 to 20 GHz	2	
8	> 20 to 28.5 GHz	3	
9	> 28.5 to 44 GHz	5	
Accuracy	± [(time since last adjustment x aging	rate) + temperature effects + line voltage e	effects + calibration accuracy]
Internal timebase reference oscillat			
Aging rate <sup>6</sup>	$< \pm 3 \times 10^{-8}$ /year or $< \pm 2.5 \times 10^{-10}$ /day after 30 days		
Initial achievable calibration accurac	$y < \pm 4 \times 10^{-8}$		
Temperature effects (typ)	$< \pm 4.5 \times 10^{-9}$ from 0 to 55 °C		
Line voltage effects (typ)	$< \pm 2 \times 10^{-10}$ for $\pm 10\%$ change		

<sup>1.</sup> In ramp sweep mode (Option 007), resolution is limited with narrow spans and slow sweep speeds. Refer to ramp sweep specifications for more information.

<sup>2.</sup> Time from GPIB trigger to frequency within 0.1 ppm of final frequency above 250 MHz or within 100 Hz below 250 MHz. CW switching speed to within 0.05% of final frequency is ≥ 5 ms (nom).

<sup>3.</sup> Add 12 ms (typ) when switching from greater than 3.2 GHz to less than 3.2 GHz.

<sup>4.</sup> With Option 1EH low band harmonic filters off. With the 1EH filters turned on, add 4 ms.

<sup>5.</sup> N is a factor used to help define certain specifications within the document.

<sup>6.</sup> Not verified by Agilent N7800A TME Calibration and Adjustment Software. Daily aging rate may be verified as a supplementary chargeable service, on request.

External reference				
Frequency	10 MHz only			
Lock range	±1.0 ppm	±1.0 ppm		
Reference output				
Frequency	10 MHz			
Amplitude	> +4 dBm into 50 Ω load (typ)			
External reference input				
Amplitude	5 dBm ± 5 dB <sup>1</sup>			
Input impedance	50 Ω (nom)			
Step (digital) sweep				
Operating modes				
operating modes	Step sweep of frequency or amplitude or both (	start to ston)		
	List sweep of frequency or amplitude or both (a			
Sweep range	(	, , , , , , , , , , , , , , , , , , , ,		
Frequency sweep	Within instrument frequency range			
Amplitude sweep	Within attenuator hold range (see "Output" see	ction)		
Dwell time	1 ms to 60 s			
Number of points				
Step sweep	2 to 65535			
List sweep	2 to 1601 per table			
Triggering	Auto, external, single, or GPIB			
Settling time	Standard	Opt UNX	Opt UNY	
Frequency <sup>2</sup>	< 9 ms (typ)	< 9 ms (typ)	< 24 ms (typ)	
Amplitude	< 5 ms (typ)	< 5 ms (typ)	< 5 ms (typ)	

To optimize phase noise use 5 dBm ± 2 dB.
 19 ms (typ) when stepping from greater than 3.2 GHz to less than 3.2 GHz.

### Ramp (analog) sweep (Option 007) <sup>1</sup>

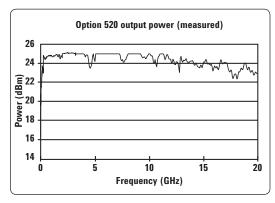
#### **Operating modes**

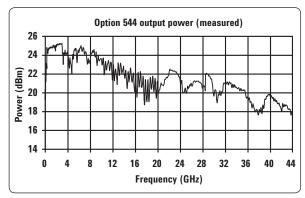
- Synthesized frequency sweep (start/stop), (center/span), (swept CW)
- · Power (amplitude) sweep (start/stop)
- Manual sweep
  - RPG control between start and stop frequencies
- Alternate sweep
  - Alternates successive sweeps between current and stored states

	Alternates successive sweeps between current and stored states			
Sweep span range	Settable from minimum <sup>2</sup> to full range			
Maximum sweep rate	Start frequency	Maximum sweep rate	Max span for 100 ms sweep	
	250 kHz to < 0.5 GHz	25 MHz/ms	2.5 GHz	
	0.5 to < 1 GHz	50 MHz/ms	5 GHz	
	1 to < 2 GHz	100 MHz/ms	10 GHz	
	2 to < 3.2 GHz	200 MHz/ms	20 GHz	
	≥ 3.2 GHz	400 MHz/ms	40 GHz	
Frequency accuracy	$\pm 0.05\%$ of span $\pm$ timebase (at 100 ms sweep time, for sweep spans less than maximum values given above). Accuracy improves proportionally as sweep time increases $^3$			
Sweep time (forward sweep, not i	ncluding bandswitch and retrace intervals)			
Manual mode	Settable 10 ms to 200 seconds	Settable 10 ms to 200 seconds		
Resolution	1 ms	I ms		
Auto mode	Set to minimum value determined by maximum sweep rate and 8757D setting			
Triggering	Auto, external, single, or GPIB			
Markers	10 independent continuously variable freq	10 independent continuously variable frequency markers		
Display	Z-axis intensity or RF amplitude pulse			
Functions	M1 to center, M1/M2 to start/stop, marker delta			
Two-tone (master/slave) measurements <sup>4</sup>	Two PSGs can synchronously track each other, with independent control of start/stop frequencies			
Network analyzer compatibility	Compatible with Agilent 8757D scalar network analyzers for making basic swept		Agilent 8757A/C/E scalar	

- 1. During ramp sweep operation, AM, FM, phase modulation, and pulse modulation are useable but performance is not specified; wideband AM and I/Q modulation are not useable.
- 2. Minimum settable sweep span is proportional to carrier frequency and sweep time. Actual sweep span may be slightly different than desired setting for spans less than [0.00004% of carrier frequency or 140 Hz] x [sweep time in seconds]. Actual span will always be displayed correctly.
- 3. Typical accuracy for sweep times > 100 ms can be calculated from the equation: [(0.005% of span)/(sweep time in seconds)] ± timebase. Accuracy is not specified for sweep times < 100 ms.
- 4. For master/slave operation use Agilent part number 8120-8806 master/slave interface cable.
- 5. GPIB system interface is not supported with 8757A/C/E, only with 8757D. As a result, some features of 8757A/C/E, such as frequency display, pass-through mode, and alternate sweep, do not function with PSG signal generators.

/linimum settable output power	–130 dBm		
Maximum output power (dBm) <sup>1</sup>		Spec (Typ)	
requency range <sup>2</sup>	cw	Standard I/Q 3	Wideband I/Q <sup>4</sup>
Option 520			
10 to 250 MHz (filters on)	+15 (+17)	+15 (+16)	+11 (+15)
> 0.25 to 2 GHz (filters on)	+16 (+17)	+16 (+17)	+14 (+16)
250 kHz to 10 MHz	+14 (+17)	+14 (+17)	(+14)
> 10 to < 60 MHz	+16 (+19)	+16 (+19)	+14 (+17)
60 to 400 MHz	+20 (+21)	+20 (+21)	+18 (+21)
> 0.4 to 3.2 GHz	+21 (+23)	+20 (+22)	+18 (+20)
> 3.2 to 10 GHz	+18 (+23)	+18 (+21)	+12 (+16)
> 10 to 20 GHz	+18 (+22)	+18 (+21)	+12 (+16)
ption 532 and 544			
10 to 250 MHz (filters on)	+14 (+16)	+14 (+16)	+9 (+12)
> 0.25 to 2 GHz (filters on)	+15 (+16)	+15 (+16)	+9 (+13)
250 kHz to 10 MHz	+13 (+16)	+13 (+17)	(+13)
> 10 to < 60 MHz	+15 (+18)	+15 (+17)	+13 (+16)
60 to 400 MHz	+19 (+21)	+18 (+20)	+17 (+20)
> 0.4 to 3.2 GHz	+20 (+22)	+17 (+20)	+17 (+19)
> 3.2 to 10 GHz	+14 (+21)	+14 (+21)	+9 (+13)
> 10 to 20 GHz	+14 (+18)	+14 (+18)	+8 (+14)
> 20 to 32 GHz	+14 (+18)	+14 (+18)	(+14)
> 32 to 40 GHz	+12 (+18)	+12 (+16)	(+13)
> 40 to 44 GHz	+10 (+13)	+10 (+15)	(+13)



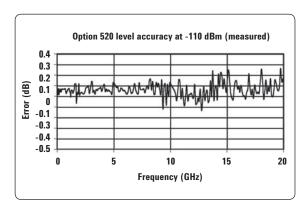


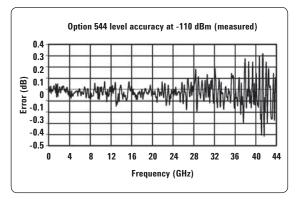
Maximum available power in CW mode (measured)

<sup>1.</sup> Maximum power specifications are warranted from 15 to 35 °C. From 0 to 15 °C, the performance is typically the same as the warranted specification. From 35 to  $55~^{\circ}$ C, the performance is typically 2 dB less than the warranted specification.

With Option 1EH low-pass filters below 2 GHz switched off, unless otherwise specified. Specifications above 2 GHz apply with filters on or off.
 Applies when using the standard I/O inputs or the internal baseband generator (Option 602) and √(I² + Q²) ≥ 0.5 V<sub>rms</sub>.
 Applies when using the wideband external differential I/O inputs (Option 016) and √(I² + Q²) ≥ 0.2 V<sub>rms</sub>.

Step attenuator <sup>1</sup>		0 to 115 dB in 5 dB steps		
Attenuator hold range				
Minimum		From $-15~\mathrm{dBm}$ to maximum specified output power with step attenuator in 0 dB position; can be offset using step attenuator		
Amplitude switching spe	eed			
ALC on		< 6 ms (typ) <sup>2</sup>		
ALC off		$<$ 10 ms (typ) (not including power search) $^{3}$		
Level accuracy <sup>4</sup> (dB)	> +10 dBm	+10 to -10 dBm	< -10 to -70 dBm	< -70 to -90 dBm
250 kHz to 2 GHz	±0.6	±0.6	±0.7	±0.8
> 2 to 20 GHz	±0.8	±0.8	±0.9	±1.0
> 20 to 32 GHz	±1.0	±0.9	±1.0	±1.7
> 32 to 44 GHz	±1.0	±0.9	±1.5	±2.0
CW level accuracy with	I/Q modulation (With PF	BS modulated data) (relative to	CW)	
With ALC on				
QAM or QPSK formats	5	±0.2 dB		
Constant-amplitude for	rmats (FSK, GMSK, etc)	±0.2 dB		
With ALC off <sup>6</sup>		±0.2 dB (typ)		

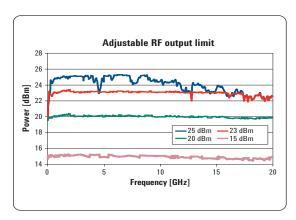




Level accuracy (measured)

- 1. The step attenuator provides coarse power attenuation to achieve low power levels. Fine power level adjustment is provided by the ALC (automatic level control) within the attenuator hold range.
- 2. To within 0.1 dB of final amplitude within one attenuator range.
- 3. To within 0.5 dB of final amplitude within one attenuator range. Add up to 50 ms when using power search.
- 4. Specifications apply in CW and list/step sweep modes over the 15 to 35 °C temperature range, with attenuator hold off (normal operating mode). Degradation outside this range, for ALC power levels > -5 dBm and frequency > 10 MHz, is typically < 0.3 dB. In ramp sweep mode (with Option 007), specifications are typical. For instruments with type-N connectors (Option 1ED), specifications apply only up to 18 GHz and typical level accuracy degrades by 0.2 dB above 18 GHz. Specifications do not apply above the maximum specified power.</p>
- 5. For Option 520, measured with symbol rate > 10 kHz and power ≤ −1 dBm. For Options 532 and 544, measured with symbol rate > 10 kHz and power ≤ −3 dBm.
- 6. Relative to ALC on, after power search is executed. When applying external I/O signals with ALC off, output level will vary directly with I/O input level.

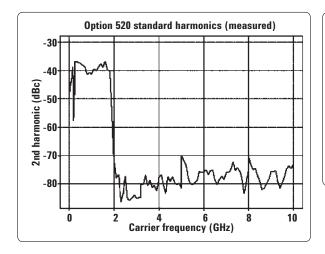
Temperature stability         0.01 dB/°C (typ)¹           User flatness correction           Number of points         2 to 1601 points/table           Number of tables         Up to 10.000, memory limited           Path loss         Arbitrary, within attenuator range           Entry modes         Remote power meter ², remote bus, manual (user edit/view)           Output impedance         50 Ω (nom)           SWR (internally leveled)         ***           Option 520         ***           250 kHz to 2 GHz         < 1.4:1 (typ)           > 2 GHz to 20 GHz         < 1.6:1 (typ)           Option 532 and 544         ***           250 kHz to 1.2 GHz         < 1.4:1 (typ)           > 1.2 GHz to 20 GHz         < 1.6:1 (typ)           > 20 GHz         < 1.6:1 (typ)           Leveling modes         Internal leveling, external detector leveling, millimeter source module, ALC off           External detector leveling         — 0.2 mV to −0.5 V (nom) (−36 dBm to +4 dBm using Agilent 33330D/E detector)           Bandwidth         Selectable 0.1 to 100 kHz (nom) (note: not intended for pulsed operation)           Maximum reverse power         1/2 Watt, 0 V <sub>DC</sub>
User flatness correctionNumber of points2 to 1601 points/tableNumber of tablesUp to 10,000, memory limitedPath lossArbitrary, within attenuator rangeEntry modesRemote power meter ², remote bus, manual (user edit/view)Output impedance50 Ω (nom)SWR (internally leveled)Option 520250 kHz to 2 GHz< 1.4:1 (typ)
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Path loss Arbitrary, within attenuator range  Entry modes Remote power meter <sup>2</sup> , remote bus, manual (user edit/view)  Output impedance 50 \( \Omega \) (nom)  SWR (internally leveled)  Option 520  250 kHz to 2 GHz
Entry modesRemote power meter ², remote bus, manual (user edit/view)Output impedance50 Ω (nom)SWR (internally leveled)Option 520250 kHz to 2 GHz< 1.4:1 (typ)> 2 GHz to 20 GHz< 1.6:1 (typ)Option 532 and 544250 kHz to 1.2 GHz< 1.4:1 (typ)> 1.2 GHz to 20 GHz< 1.6:1 (typ)> 20 GHz< 1.8:1 (typ)Leveling modesInternal leveling, external detector leveling, millimeter source module, ALC offExternal detector leveling— 0.2 mV to -0.5 V (nom) (-36 dBm to +4 dBm using Agilent 33330D/E detector)BandwidthSelectable 0.1 to 100 kHz (nom) (note: not intended for pulsed operation)Maximum reverse power1/2 Watt, 0 VDC
Output impedance         50 Ω (nom)           SWR (internally leveled)           Option 520           250 kHz to 2 GHz         < 1.4:1 (typ)
SWR (internally leveled) Option 520  250 kHz to 2 GHz
Option 520 250 kHz to 2 GHz
250 kHz to 2 GHz
> 2 GHz to 20 GHz
Option 532 and 544  250 kHz to 1.2 GHz
250 kHz to 1.2 GHz
> 1.2 GHz to 20 GHz < 1.6:1 (typ)  > 20 GHz < 1.8:1 (typ)  Leveling modes Internal leveling, external detector leveling, millimeter source module, ALC off  External detector leveling  Range -0.2 mV to -0.5 V (nom) (-36 dBm to +4 dBm using Agilent 33330D/E detector)  Bandwidth Selectable 0.1 to 100 kHz (nom) (note: not intended for pulsed operation)  Maximum reverse power 1/2 Watt, 0 VDC
> 20 GHz < 1.8:1 (typ)  Leveling modes Internal leveling, external detector leveling, millimeter source module, ALC off  External detector leveling  Range -0.2 mV to -0.5 V (nom) (-36 dBm to +4 dBm using Agilent 33330D/E detector)  Bandwidth Selectable 0.1 to 100 kHz (nom) (note: not intended for pulsed operation)  Maximum reverse power 1/2 Watt, 0 VDC
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Bandwidth Selectable 0.1 to 100 kHz (nom) (note: not intended for pulsed operation)  Maximum reverse power 1/2 Watt, 0 V <sub>DC</sub>
Maximum reverse power 1/2 Watt, 0 V <sub>DC</sub>
Adjustable RF output limit
Function Protects external devices by limiting maximum RF output; operates in all leveling modes (internal, external, source module)
Range User-adjustable from +15 dBm to maximum output power
Accuracy
+15 to +25 dBm
$> +25 \text{ dBm}$ $\pm 1.5 \text{ dB (typ)}$
Resolution 1 dB
Response time 30 µsec (measured)
Adjustment Can be locked to prevent accidental change

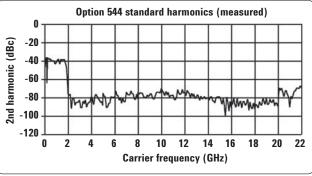


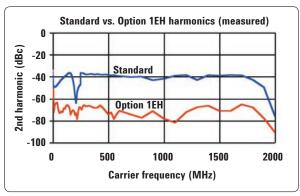
### RF output limit (measured)

- Options 532 and 544: 0.02 dB/°C (typ) above 2 GHz.
   Compatible with Agilent EPM Series (E4418B and E4419B) power meters.

Spectral purity				
Harmonics <sup>1</sup> (dBc at +10 dBm or maximum specified output power, whichever is lower)				
Frequency	Standard			
< 1 MHz	-25 dBc (typ)			
1 to < 10 MHz	–25 dBc			
10 to < 60 MHz	–28 dBc			
10 to $<$ 60 MHz with Option 1EH filters on $^{\rm 2}$	–45 dBc			
0.06 to 2 GHz	-30 dBc			
0.06 to 2 GHz with Option 1EH filters on $^{\mathrm{2}}$	–55 dBc			
> 2 to 20 GHz	–55 dBc			
> 20 to 44 GHz	-45 dBc (typ)			







Harmonics (measured)

<sup>1.</sup> Specifications are typical for harmonics beyond specified frequency. Specifications are with Option 1EH low-pass filters below 2 GHz off, unless noted.

<sup>2.</sup> Below 250 MHz in ramp sweep mode (Option 007), Option 1EH filters are always off. Refer to harmonic specification with filters off.

Sub-harmonics <sup>1</sup> (At +10 dBm or ma	vimum enecified output nower wh	nichovar ic lower)			
•	ximum specimen output power, wi	•			
250 kHz to 10 GHz > 10 GHz to 20 GHz		None < -60 dBc			
> 10 GHz to 20 GHz > 20 GHz to 44 GHz		< -00 dBc			
Non-harmonics $^{2,3}$ (dBc at +10 dBm or maximum specified output power, whichever is lower)					
Frequency	Offsets > 3 kHz (Standard) Spec (typ)	Offsets > 300 Hz (Opt UNX or UNY) Spec (typ)	Offsets > 3 kHz (Option UNY) Spec	Line-related (≤ 300 Hz) (typ)	
250 kHz to 250 MHz	-58 (-62) <sup>4</sup>	-58 (-62) <sup>4</sup>	-58	(-55)	
> 250 MHz to 1 GHz	-80 (-88)	-80 (-88)	-80	(-55)	
> 1 to 2 GHz	-74 ( <del>-</del> 82)	-74 (-82)	-80	(-55)	
> 2 to 3.2 GHz	-68 (-76)	-68 (-76)	-76	(-55)	
> 3.2 to 10 GHz	-62 (-70)	<b>-62</b> ( <b>-70</b> )	-70	(-50)	
> 10 to 20 GHz	-56 (-64)	-56 (-64)	-64	(-45)	
> 20 to 28.5 GHz	-52 (-60)	-52 (-60)	-58	(-39)	
> 28.5 to 44 GHz	-48 (-56)	-48 (-56)	-52	(-37)	
Residual FM (RMS, 50 Hz to 15 kHz bandwidth)					
CW mode		< N x 8 Hz (typ)			
CW mode with Option UNX or UNY		< N x 4 Hz (typ)			
Ramp sweep mode		< N x 1 kHz (typ)			
Broadband noise (CW mode at +10 c	IBm or maximum specified output	power, whichever is lower, for	offsets > 10 MHz)		
> 2.4 to 20 GHz		<-148 dBc/Hz (typ)			
> 20 GHz		<-141 dBc/Hz (typ)			
Measured RMS jitter: <sup>5</sup>					
Standard carrier frequency	SONET/SDH data rates	RMS jitter bandwidth	Unit intervals (µUI)	Time (fs)	
155 MHz	155 MB/s	100 Hz to 1.5 MHz	25	158	
622 MHz	622 MB/s	1 kHz to 5 MHz	21	34	
2.488 GHz	2488 MB/s	5 kHz to 20 MHz	57	23	
9.953 GHz	9953 MB/s	10 kHz to 80 MHz	152	15	
39.812 GHz	39812 MB/s	40 kHz to 320 MHz	627	16	

<sup>1.</sup> Sub-harmonics are defined as carrier freq \* (x/y), where x and y are integers, and x is not an integer multiple of y. Specifications are typical for sub-harmonics beyond specified frequency range. Specifications are typical when I/Q modulation is on.

<sup>2.</sup> Performance is typical for spurs at frequencies above the maximum operating frequency of the instrument. Specifications apply for CW mode, without modulation. In ramp sweep mode (Option 007), performance is typical for offsets > 1 MHz.

<sup>3.</sup> Excluding external mechanical vibration.

<sup>4.</sup> For offsets > 10 kHz.

<sup>5.</sup> Calculated from phase noise performance in CW mode only at +10 dBm. For other frequencies, data rates, or bandwidths, please contact your sales representative.

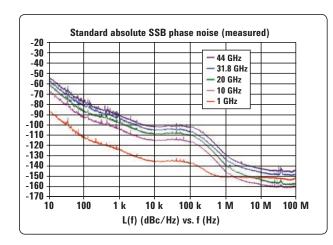
Option UNX carrier frequency	SONET/SDH data rates	RMS jitter bandwidth	Unit intervals (µUI)	Time (fs)
155 MHz	155 MB/s	100 Hz to 1.5 MHz	23	151
622 MHz	622 MB/s	1 kHz to 5 MHz	19	30
2.488 GHz	2488 MB/s	5 kHz to 20 MHz	56	22
9.953 GHz	9953 MB/s	10 kHz to 80 MHz	152	15
39.812 GHz	39812 MB/s	40 kHz to 320 MHz	626	16
Option UNY carrier frequency	SONET/SDH data rates	RMS jitter bandwidth	Unit intervals (µUI)	Time (fs)
155 MHz	155 MB/s	100 Hz to 1.5 MHz	21	130
622 MHz	622 MB/s	1 kHz to 5 MHz	22	35
2.488 GHz	2488 MB/s	5 kHz to 20 MHz	53	21
9.953 GHz	9953 MB/s	10 kHz to 80 MHz	96	10
39.812 GHz	39812 MB/s	40 kHz to 320 MHz	518	13
SSB phase noise (dBc/Hz) (CW) $^{\rm 1}$		20 kHz offset from car	rier	
Frequency		Spec	Typical	
250 kHz to 250 MHz		-130	-134	
> 250 to 500 MHz		-134	-138	
> 500 MHz to 1 GHz		-130	-134	
> 1 to 2 GHz		-124	-128	
> 2 to 3.2 GHz		-120	-124	
> 3.2 to 10 GHz		-110	-113	
> 10 to 20 GHz		-104	-108	
> 20 to 28.5 GHz		-100	-104	
> 28.5 GHz		-96	-100	

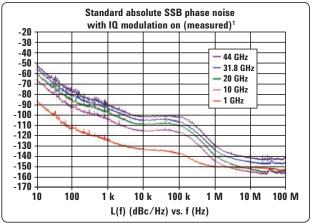
<sup>1.</sup> Phase noise specifications are warranted from 15 to 35 °C excluding external mechanical vibration. Measured at +10 dBm or maximum specified output power, whichever is less.

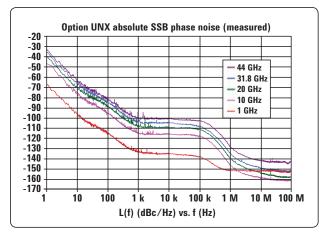
Option UNX: absolute S	SB phase noise (d	Bc/Hz) (CW) <sup>1, 2</sup>	Offset fro	om carrier		
Frequency	1 Hz spec (typ)	10 Hz spec (typ)	100 Hz spec (typ)	1 kHz spec (typ)	10 kHz spec (typ)	100 kHz spec (typ)
250 kHz to 250 MHz	-58 (-66)	-87 (-94)	-104 (-120)	-121 (-128)	-128 (-132)	-130 (-133)
> 250 to 500 MHz	-61 (-72)	-88 (-98)	-108 (-118)	-125 (-132)	-132 (-136)	-136 (-141)
> 500 MHz to 1 GHz	<b>–57</b> ( <b>–65</b> )	-84 (-93)	-101 (-111)	-121 (-130)	-130 (-134)	-130 (-135)
> 1 to 2 GHz	<b>–51</b> ( <b>–58</b> )	<b>-79</b> ( <b>-86</b> )	-96 (-106)	-115 (-124)	-124 (-129)	-124 (-129)
> 2 to 3.2 GHz	-46 (-54)	<b>−74 (−82)</b>	-92 (-102)	-111 (-120)	-120 (-124)	-120 (-124)
> 3.2 to 10 GHz	-37 (-44)	-65 (-72)	-81 (-92)	-101 (-109)	-110 (-114)	-110 (-115)
> 10 to 20 GHz	-31 (-38)	-59 (-66)	<b>-75</b> ( <b>-87</b> )	-95 (-106)	-104 (-107)	-104 (-109)
> 20 to 28.5 GHz	-25 (-34)	-56 (-62)	-72 (-83)	-92 (-102)	-100 (-103)	-100 (-105)
> 28.5 to 44 GHz	-20 (-30)	<b>–51</b> ( <b>–58</b> )	-68 (-77)	-88 (-97)	-96 (-99)	-96 (-101)
Option UNY: absolute S	SB phase noise (dl	Bc/Hz) (CW) <sup>1, 2</sup>	Offset fr	om carrier, optimize	d for less than 150 kH	lz (mode 1)
Frequency	1 Hz spec (typ)	10 Hz spec (typ)	100 Hz spec (typ)	1 kHz spec (typ)	10 kHz spec (typ)	100 kHz spec (typ)
250 kHz to 250 MHz	-64 (-70)	-92 (-98)	-115 (-125)	-123 (-135)	-138 (-144)	-141 (-144)
> 250 to 500 MHz	-67 (-77)	-93 (-101)	-111 (-116)	-125 (-132)	-138 (-144)	-142 (-147)
> 500 MHz to 1 GHz	-62 (-69)	<b>-91</b> ( <b>-99</b> )	-105 (-111)	-121 (-128)	-138 (-143)	-138 (-144)
> 1 to 2 GHz	-57 (-63)	-86 (-90)	-100 (-106)	-115 (-121)	-133 (-138)	-133 (-139)
> 2 to 3.2 GHz	-52 (-58)	<b>–81</b> ( <b>–84</b> )	-96 (-102)	-111 (-117)	-128 (-134)	-128 (-134)
> 3.2 to 10 GHz	-43 (-49)	-72 (-76)	-85 (-91)	-101 (-107)	-120 (-126)	-120 (-125)
> 10 to 20 GHz	-37 (-43)	-66 (-70)	-79 (-85)	-95 (-101)	-114 (-121)	-114 (-119)
> 20 to 28.5 GHz	-31 (-37)	-60 (-66)	-73 (-79)	-89 (-95)	-108 (-113)	-108 (-113)
> 28.5 to 44 GHz	-26 (-32)	-54 (-60)	-68 (-73)	-84 (-90)	-102 (-107)	-102 (-107)
Option UNX: residual SSB phase noise (dBc/Hz) (CW) 1, 2 Offset from carrier						
Frequency	1 Hz spec (typ)	10 Hz spec (typ)	100 Hz spec (typ)	1 kHz spec (typ)	10 kHz spec (typ)	100 kHz spec (typ)
250 kHz to 250 MHz	(-94)	-100 (-107)	-110 (-118)	-120 (-126)	-128 (-132)	-130 (-133)
> 250 to 500 MHz	(-101)	<b>–105 (–112)</b>	-115 (-122)	-124 (-131)	-132 (-136)	-136 (-141)
> 500 MHz to 1 GHz	(-94)	-100 (-107)	-110 (-118)	-120 (-126)	-130 (-134)	-130 (-134)
> 1 to 2 GHz	(-89)	-96 (-101)	-104 (-112)	-114 (-120)	-124 (-129)	-124 (-129)
> 2 to 3.2 GHz	(-85)	-92 (-97)	-100 (-108)	-110 (-116)	-120 (-124)	-120 (-124)
> 3.2 to 10 GHz	(-74)	(-87)	(-98)	(-106)	(-114)	(–115)
Option UNY: residual SS	SB phase noise (dE	Bc/Hz) (CW) <sup>1, 2</sup>	Offset fro	om carrier, optimized	l for less than 150 kH	z (mode 1)
Frequency	1 Hz spec (typ)	10 Hz spec (typ)	100 Hz spec (typ)	1 kHz spec (typ)	10 kHz spec (typ)	100 kHz spec (typ)
250 kHz to 250 MHz	(-94)	-100 (-107)	-110 (-118)	-123 (-135)	-138 (-144)	-141 (-144)
> 250 to 500 MHz	(-101)	-105 ( <del>-</del> 112)	-115 (-122)	-124 (-130)	-138 (-144)	-140 (-147)
> 500 MHz to 1 GHz	(-94)	-100 (-108)	-110 (-118)	-120 (-126)	-135 (-142)	-135 (-145)
> 1 to 2 GHz	(-89)	-96 (-101)	-104 (-112)	<b>–115</b> ( <b>–121</b> )	-133 (-138)	-133 (-139)
> 2 to 3.2 GHz	(-85)	-92 (-97)	-100 (-108)	-111 ( <del>-</del> 117)	-128 (-134)	-128 (-134)
> 3.2 to 10 GHz	(-74)	(-87)	(-98)	(-104)	(-126)	(-125)

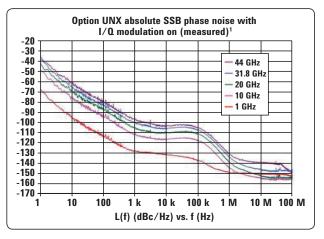
 $<sup>1. \</sup>quad \textit{Phase noise specifications are warranted from 15 to 35 °C. Excluding external mechanical vibration. Option UNY specifications at 1 kHz offset apply from 25 to 35 °C. Excluding external mechanical vibration.}$ 

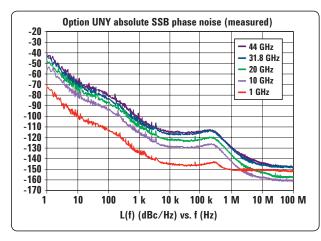
<sup>2.</sup> Measured at +10 dBm or maximum specified power, whichever is less.

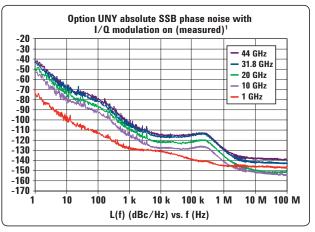






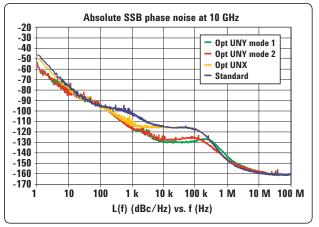


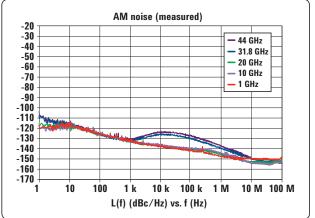


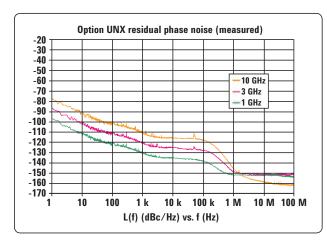


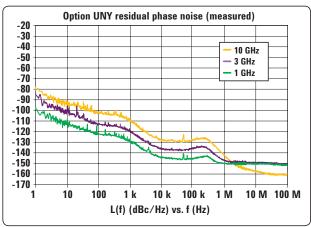
Measured phase noise (data collected with the E5500 and plotted without spurs) Option UNY phase noise optimized for offsets less than 150 kHz (mode 1)

<sup>1.</sup> I/Q modulator attenuator set to auto. External I/Q input level  $\sqrt{(I^2 + Q^2)} = 0.5 V_{rms}$ 









Measured phase noise (data collected with the E5500 and plotted without spurs) Option UNY phase noise optimized for offsets less than 150 kHz (mode 1)

Maximum deviation <sup>1</sup> (normal mode)	Frequency	Max deviation		
	250 kHz to 250 MHz	2 MHz		
	> 250 to 500 MHz	1 MHz		
	> 500 MHz to 1 GHz	2 MHz		
	> 1 GHz to 2 GHz	4 MHz		
	> 2 GHz to 3.2 GHz	8 MHz		
	> 3.2 GHz to 10 GHz	16 MHz		
	> 10 GHz to 20 GHz	32 MHz		
	> 20 GHz to 28.5 GHz	48 MHz		
	> 28.5 GHz to 44 GHz	80 MHz		
Resolution	0.1% of deviation or 1 Hz, whichever is greater			
Deviation accuracy	$<\pm3.5\%$ of FM deviation + 20 Hz (1 kHz rate, deviations $<$ N x 800 kHz)			
Modulation frequency response <sup>2</sup> (at 100	) kHz deviation)			
Path [coupling]	1 dB bandwidth	3 dB bandwidth (typ)		
Standard or Option UNX				
FM path 1 [DC]	DC to 100 kHz	DC to 10 MHz		
FM path 2 [DC]	DC to 100 kHz	DC to 1 MHz		
FM path 1 [AC]	20 Hz to 100 kHz	5 Hz to 10 MHz		
FM path 2 [AC]	20 Hz to 100 kHz	5 Hz to 1 MHz		
Option UNY				
FM path 1 [DC]	DC to 100 kHz	DC to 9.3 MHz		
FM path 2 [DC]	DC to 100 kHz	DC to 1 MHz		
FM path 1 [AC]	20 Hz to 100 kHz	5 Hz to 9.3 MHz		
FM path 2 [AC]	20 Hz to 100 kHz	5 Hz to 1 MHz		
DC FM <sup>3</sup> carrier offset	±0.1% of set deviation + (N x 8 Hz)			
Distortion	< 1% (1 kHz rate, deviations < N x 80	< 1% (1 kHz rate, deviations < N x 800 kHz)		
Sensitivity	±1 V <sub>peak</sub> for indicated deviation			
Paths	FM1 and FM2 are summed internally for composite modulation. Either path may be switched to any one of the modulation sources: Ext1, Ext2, internal1, internal2. The FM2 path is limited to a maximum rate of 1 MHz. The FM2 path must be set to a deviation less than FM1. To avoid distortion and clipping, signals applied with any combination of FM1, FM2, or FM1+FM2 should not exceed 1V <sub>peak</sub> .			

<sup>1.</sup> Through any combination of path1, path2, or path1 + path2.

Specifications apply in CW and list/step sweep modes. During ramp sweep operation (Option 007), 3 dB bandwidth is typically 50 kHz to 10 MHz (FM1 path), and 50 kHz to 1 MHz (FM2 path).
 At the calibrated deviation and carrier frequency, within 5 °C of ambient temperature at time of user calibration.

Maximum deviation <sup>1</sup>				
Standard or Option UNX	Frequency	100 kHz BW mode	1 MHz BW	mode
	250 kHz to 250 MHz	20 rad	2 rad	
	> 250 to 500 MHz	10 rad	1 rad	
	> 500 MHz to 1 GHz	20 rad	2 rad	
	> 1 GHz to 2 GHz	40 rad	4 rad	
	> 2 GHz to 3.2 GHz	80 rad	8 rad	
	> 3.2 GHz to 10 GHz	160 rad	16 rad	
	> 10 GHz to 20 GHz	320 rad	32 rad	
	> 20 GHz to 28.5 GHz	480 rad	48 rad	
	> 28.5 GHz to 44 GHz	800 rad	80 rad	
Option UNY	Frequency	1 MHz BW mode	10 MHz BW	mode
	250 kHz to 250 MHz	2 rad	0.2 rad	
	> 250 to 500 MHz	1 rad	0.1 rad	
	> 500 MHz to 1 GHz	2 rad	0.2 rad	
	> 1 GHz to 2 GHz	4 rad	0.4 rad	
	> 2 GHz to 3.2 GHz	8 rad	0.8 rad	
	> 3.2 GHz to 10 GHz	16 rad	1.6 rad	
	> 10 GHz to 20 GHz	32 rad	3.2 rad	
	> 20 GHz to 28.5 GHz	48 rad	4.8 rad	
	> 28.5 GHz to 44 GHz	80 rad	8.0 rad	
Resolution	0.1% of set deviation			
Deviation accuracy	< ±5% of deviation + 0.01 radians otherwise)	< ±5% of deviation + 0.01 radians (1 kHz rate, with 1MHz BW mode for Option UNY or 100kHz BW mode otherwise)		
Modulation frequency response <sup>2</sup>	Rates (3 dB bandwidth)	Standard	UNX	UNY
100 kHz BW mode	DC to 100 kHz	Normal	Normal	n/a
1 MHz BW mode	DC to 1 MHz (typ) <sup>3</sup>	High	High	Normal
10 MHz BW mode	DC to 10 MHz (typ)	n/a	n/a	High
Distortion				
Standard or Option UNX	< 1% (1 kHz rate, total harmonic distortion (THD), deviation < N x 80 rad, 100 kHz BW mode)			
Option UNY	< 1% (1 kHz rate, total harmonic distortion (THD), deviation < N x 8 rad, 1 MHz BW mode)			
Sensitivity	±1 V <sub>peak</sub> for indicated deviation			
Paths	$\phi$ M1 and $\phi$ M2 are summed internally for composite modulation; either path may be switched to any one of the modulation sources: ext1, ext2, internal1, internal2; the $\phi$ M2 path is limited to a maximum rate of 1 MH the $\phi$ M2 path must be set to a deviation less than $\phi$ M1; to avoid distortion and clipping, signals applied we any combination of $\phi$ M1, $\phi$ M2, or $\phi$ M1+ $\phi$ M2 should not exceed 1V <sub>peak</sub> .			

Through any combination of path1, path2, or path1 + path2.
 Specifications apply in CW and list/step sweep modes. During ramp sweep operation (Option 007), 3 dB bandwidth is typically 50 kHz to 1 MHz (high BW mode).
 Path 1 is useable to 4 MHz for external inputs less than 0.3 V<sub>peak</sub>.

Amplitude modulation <sup>1</sup> (0	Linear mode	Exponential (log) mode (downward modulation only)		
Maximum		, , , , , , , , , , , , , , , , , , ,		
ALC on	> 90%	> 20 dB		
ALC off with power search <sup>2</sup> or ALC on with deep AM <sup>3</sup>	> 95%	> 40 dB		
Settable	0 to 100%	0 to 40 dB		
Sensitivity	0 to 100%/V	0 to 40 dB/V		
Resolution	0.1%	0.01 dB		
Accuracy (1 kHz rate)	< ± (6% of setting + 1%)	$< \pm (2\% \text{ of setting} + 0.2 \text{ dB})$		
External input (selectable polarity)				
Sensitivity for indicated depth	1 V <sub>peak</sub>	–1 V or +1 V		
Maximum allowable	±1 V	±3.5 V		
Rates (3 dB bandwidth, 30% depth)				
DC coupled	0 to 100 kHz			
AC coupled	10 Hz to 100 kHz (useable to	1 MHz)		
Distortion (1 kHz rate, linear mode, total	al harmonic distortion (THD))			
30% AM	< 1.5%			
60% AM	< 2%			
Paths		AM1 and AM2 are summed internally for composite modulation. Either path may be switched to any one of the modulation sources: ext1, ext2, internal1, internal2		
External modulation inputs	(Ext1 & Ext2) (Option L	JNT)		
Modulation types	AM, FM, and ΦM	AM, FM, and ΦM		
Input impedance	50 or 600 $\Omega$ (nom), switched			
High/low indicator	100 Hz to 10 MHz BW, activa	ated when input level error exceeds 3% (nom), ac coupled inputs only		
Internal modulation source	e (Option UNT)			
Dual function generators	Provide two independent sig	nals (internal1 and internal2) for use with AM, FM, φM, or LF out		
Waveforms	Sine, square, positive ramp, sine 4	Sine, square, positive ramp, negative ramp, triangle, Gaussian noise, uniform noise, swept sine, dua sine $^{\rm 4}$		
Rate range				
Sine	0.5 Hz to 1 MHz			
Square, ramp, triangle	0.5 Hz to 100 kHz	0.5 Hz to 100 kHz		
Resolution	0.5 Hz			
Accuracy	Same as timebase	Same as timebase		
LF out				
Output	Internal1 or internal2; also pr	Internal1 or internal2; also provides monitoring of internal1 or internal2 when used for AM, FM, or ΦM		
Amplitude	0 to 3 $V_{peak}$ (nom) into 50 $\Omega$	0 to 3 $V_{peak}$ (nom) into 50 $\Omega$		
Output impedance	50 Ω (nom)	• • •		
Swept sine mode	(frequency, phase continuou	(frequency, phase continuous)		
Operating modes	Triggered or continuous swe	Triggered or continuous sweeps		
Frequency range	1 Hz to 1 MHz			
Sweep rate	0.5 to 100,000 sweeps/s, equivalent to sweep times 10 μs to 2 s			
Resolution		0.5 Hz (0.5 sweep/s)		
	( <b>3.1.55</b> p, 5)			

- 1. AM specifications are typical. For carrier frequencies below 2 MHz, AM is useable but not specified. Unless otherwise stated, specifications apply with ALC on, deep AM off, and envelope peaks within ALC operating range (–15 dBm to maximum specified power, excluding step attenuator setting).
- 2. ALC off is used for narrow pulse modulation and/or high AM depths, with envelope peaks below ALC operating range. Carrier power level will be accurate after a power search is executed.
- 3. ALC on with deep AM provides high AM depths together with closed-loop internal leveling. This mode must be used with a repetitive AM waveform (frequency > 10 Hz) with peaks > -5 dBm (nominal, excluding step-attenuator setting).
- 4. Internal2 is not available when using swept sine or dual sine modes.

Wideband AM	
Rate (typical 1 dB bandwidth)	
ALC on	1 kHz to 80 MHz
ALC off	DC to 80 MHz
External I input	
Sensitivity	0.5  V = 100%
Input impedance	50 Ω (nom)

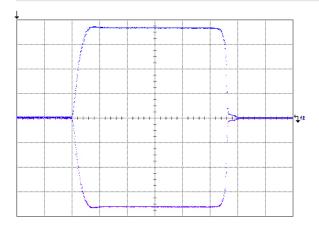
	()			
Pulse modulation <sup>1</sup> (Option UNU or UNW)				
On/off ratio	Option UNU	Option UNW		
	80 dB (typical)	80 dB		
Rise/fall times (Tr, Tf)				
50 to 400 MHz	10 ns (typical)	15 ns (10 ns typical)		
> 400 MHz	6 ns (typical)	10 ns (6 ns typical)		
Minimum pulse width				
ALC on	1 μs	1 µs		
ALC off				
50 to 400 MHz	150 ns	30 ns		
> 400 MHz	150 ns	20 ns		
Repetition frequency				
ALC on	10 Hz to 500 kHz	10 Hz to 500 kHz		
ALC off	dc to 3 MHz	dc to 10 MHz		
Level accuracy (relative to CW)				
ALC on	±0.5 dB (0.15 dB typical)	±0.5 dB (0.15 dB typical)		
ALC off with power search <sup>2</sup>				
50 MHz to 3.2 GHz	±0.7 dB (typical)	±0.7 dB (typical)		
> 3.2 GHz	±0.5 dB (typical)	±0.5 dB (typical)		
Width compression (RF width relative to video out)	±5 ns (typical)	±5 ns (typical)		
Video feed-through <sup>3</sup>				
50 to 250 MHz	< 3% (typical)	< 3% (typical)		
> 250 to 400 MHz	< 11% (typical)	< 11% (typical)		
> 0.4 to 3.2 GHz	< 6% (typical)	< 6% (typical)		
> 3.2 GHz	< 2 mV pk-pk (typ)	< 2 mV pk-pk (typ)		
Video delay (ext input to video)	50 ns (nom)	50 ns (nom)		

With ALC off, specs apply after the execution of power search. Specifications apply with Atten Hold Off (default mode for instruments with attenuator), or ALC level between -5 and +10 dBm or maximum specified power, whichever is lower. Below 50 MHz, pulse modulation is useable; however performance is not warranted.

<sup>2.</sup> Power search is a calibration routine that improves level accuracy with ALC off. The instrument microprocessor momentarily closes the ALC loop to find the modulator drive setting necessary to make the quiescent RF level equal to an entered value, then opens the ALC loop while maintaining that modulator drive setting. When executing power search, RF power will be present for typically 10 to 50 ms; the step attenuator can be set to automatically switch to maximum attenuation to protect sensitive devices. Power search can be configured to operate either automatically or manually at the carrier frequency, or over a user-definable frequency range. Power search may not operate above the maximum specified output power.

<sup>3.</sup> With step attenuator in 0 dB position. Above 3.2 GHz, video feed-through decreases with step attenuator setting. Below 3.2 GHz, video feed-through is expressed as a percentage of RF output level.

RF delay (video to RF output)	Option UNU	Option UNW
50 to 250 MHz	35 ns (nominal)	35 ns (nominal)
> 0.25 to 3.2 GHz	25 ns (nominal)	25 ns (nominal)
> 3.2 GHz	30 ns (nominal)	30 ns (nominal)
Pulse overshoot	< 10% (typ)	< 10% (typ)
Input level	+1 V = RF on	+1 V = RF on
Input impedance	50 Ω (nom)	50 Ω (nom)

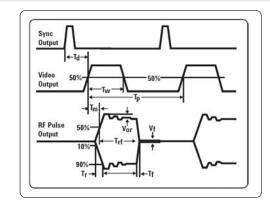


Measured pulse modulation envelope Frequency = 9 GHz, amplitude = 10 dBm, ALC off, 10 ns/div

Internal	nulse d	generator	(Ontion	HMH	or	HMW
IIILGIIIAI	puloc t	Joniorator	(Option	OIVO	UI.	

	, , , , , , , , , , , , , , , , , , ,
Modes	Free-run, triggered, triggered with delay, doublet, and gated. Triggered with delay, doublet, and gated require external trigger source.
Period (PRI) (Tp)	70 ns to 42 s (repetition frequency: 0.024 Hz to 14.28 MHz)
Pulse width (Tw)	10 ns to 42 s
Delay (Td)	
Free-run mode	0 to ±42 s
Triggered with delay and doublet modes	75 ns to 42 s with ±10 ns jitter
Resolution	10 ns (width, delay, and PRI)

- Td video delay (variable)
- Tw video pulse width (variable)
- Tp Pulse period (variable)
- · Tm RF delay
- Trf RF pulse width
- Tf RF pulse fall time
- Tr RF pulse rise time
- · Vor pulse overshoot
- · Vf video feedthrough



### Simultaneous modulation

All modulation types (FM, AM,  $\Phi$ M, pulse and I/Q) may be simultaneously enabled except: FM with  $\Phi$ M, linear AM with exponential AM, and wideband AM with I/Q. AM, FM, and  $\Phi$ M can sum simultaneous inputs from any two sources (Ext1, ext2, internal1, or internal2). Any given source (Ext1, ext2, internal1, or internal2) may be routed to only one activated modulation type.

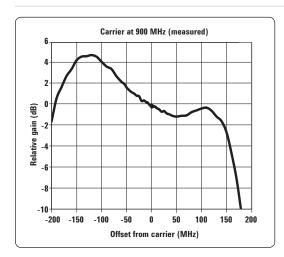
### Vector modulation <sup>1</sup> (Standard I/Q inputs)

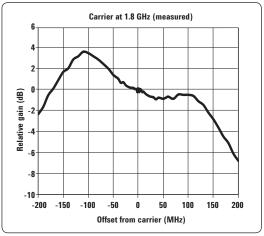
### External I/Q inputs

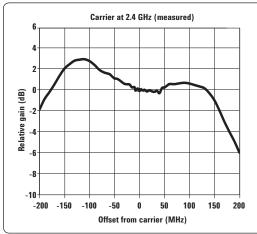
Input impedance switched  $\,$  50 or 600  $\Omega$  (nom)

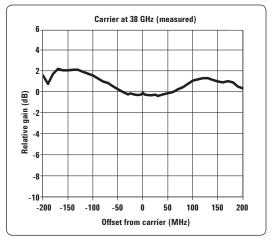
Input range <sup>2</sup> Minimum 0.1 V<sub>rms</sub>, maximum 1V<sub>peak</sub>

Flatness ±1 dB within ±40 MHz of carrier (with ALC off) (typ)









I/O frequency response (measured) 3

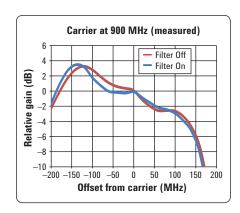
RF path filters	Carrier frequency	Nominal filter cutoff
	≤ 250 MHz	300 MHz low-pass filter
	> 250 to 396 MHz	220 to 420 MHz bandpass filter
	> 396 to 628 MHz	350 to 650 MHz bandpass filter
	> 628 to 1000 MHz	1040 MHz low-pass filter
	> 1.0 to 1.5 GHz	1.6 GHz low-pass filter

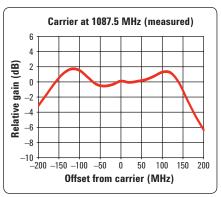
- 1. With Option 007, vector modulation is not useable in ramp sweep mode. With Option 1EH, specifications apply with filters off.
- 2. Different RMS levels are accommodated by adjusting the internal I/O modulator attenuator, which may be either manually or automatically set. The minimum input level required to maintain RF level accuracy is  $\sqrt{(l^2 + Q^2)} = 0.1 \text{ V}_{rms}$ .
- 3. Sine wave response, measured with input level = 0.5 V<sub>rms</sub> on one channel, and ALC off. For carrier frequencies at or below 1.5 GHz, modulation frequency response within ±150 MHz of carrier may be limited by RF chain filtering.

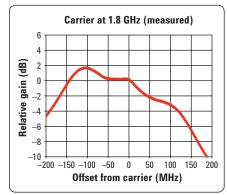
I/O adjustments	
I/Q adjustments	
I & Q offsets	External inputs (600 Ω): ±5 Volts
	External inputs (50 $\Omega$ ): $\pm 50\%$
	Internal baseband generator: ±50%
I/Q attenuation	0 to 40 dB
I/Q gain balance	±4 dB
I/Q quadrature skew	±10 ° range (typ)
Low pass filter	Selectable 40 MHz or through path
I/Q baseband outputs	
Differential	ı, ī, a, ā
Single ended	I, Q
Frequency range	DC to 40 MHz
Output voltage into 50 $\Omega$	1.5 V <sub>peak-to-peak</sub> (typ)
DC offset adjustments	±3 V
DC offset resolution	1 mV
Low pass filter	Selectable 40 MHz or through path
Wideband external differential I	/Q inputs <sup>1</sup> (Option 016)

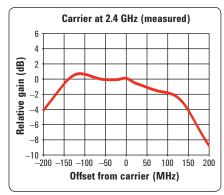
Wideband external differential I/Q inputs <sup>1</sup> (Option 016)		
Input	250 kHz to 3.2 GHz	3.2 to 44 GHz
Input (baseband) frequency range	DC to 130 MHz (nom)	DC to 1.0 GHz <sup>2</sup>
Input impedance	50 Ω (nom)	50 Ω (nom)
Recommended input level	–1 dBm	0 dBm (nom)
Maximum input voltage	±1 V <sub>DC</sub>	±1 V <sub>DC</sub>
I/Q offset adjustments	±50%	±50%
I/Q quadrature skew	±10 degrees	±10 degrees (nom)

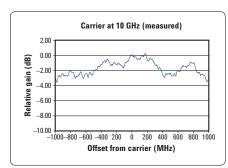
With Option 007, vector IQ modulation is not useable in ramp sweep mode.
 Modulation frequency response within ±1 GHz of the carrier frequency may be limited by the RF chain cutoff frequencies.

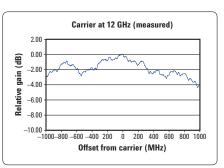


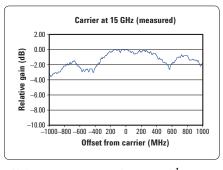


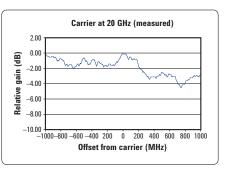












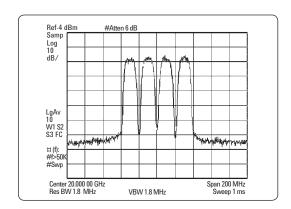
I/Q frequency response (measured) 1

Sine wave response, measured with input level = 0.2 V<sub>rms</sub> on one channel, and ALC off. Modulation frequency response may be limited by RF chain filtering. For operation near a filter edge, filters can be bypassed using software commands to increase modulation bandwidth.

RF path filters <sup>1</sup>	
Carrier frequency	Nominal filter cutoff frequencies
> 3.2 to 5 GHz	5.5 GHz low-pass filter
> 5 to 8 GHz	8.9 GHz low-pass filter
> 8 to 12.8 GHz	13.9 GHz low-pass filter
> 12.8 to 20 GHz	22.5 GHz low-pass filter
> 20 to 24 GHz	19.6 to 24.5 GHz bandpass filter
> 24 to 28.5 GHz	23.5 to 29.0 GHz bandpass filter
> 28.5 to 32 GHz	28.0 to 32.5 GHz bandpass filter
> 32 to 36 GHz	31.7 to 36.5 GHz bandpass filter
> 36 to 40 GHz	35.5 to 40.4 GHz bandpass filter
> 40 to 44 GHz	39.5 to 44.3 GHz bandpass filter
Internal baseband generator, arbitra	ary waveform mode (Option 602)
Channels	2 [I and Q]
Resolution	16 bits [1/65,536]
Baseband waveform memory	
Length (playback)	64 megasamples (MSa/channel)
Length (non-volatile storage)	1.2 gigasamples (GSa) on 8 GB removable flash memory (Option 009)
Waveform segments	
Segment length	60 samples to 64 MSa
Maximum number of segments	8,192
Minimum memory allocation	256 samples or 1 kbyte blocks
Waveform sequences	
Sequencing	Continuously repeating
Maximum number of sequences	16,384
Maximum segments/sequence	32,768
Maximum segment repetitions	65,536

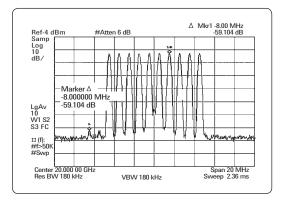
<sup>1.</sup> Modulation frequency response within ±1 GHz of the carrier frequency may be limited by the RF chain cutoff frequencies. For operation near a filter edge, filters can be bypassed using software commands to increase modulation bandwidth.

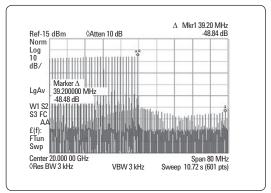
Sample rate         1 Hz to 100 MHz           Resolution         0.001 Hz           Accuracy         Same as timebase +2-42 [in non-integer applications]           Reconstruction filter: [fixed]         50 MHz [used for all symbol rates]           Baseband spectral purity [full scale sine wave]         Harmonic distortion           Phase noise         <-127 dBc/Hz (typ) (baseband output of 10 MHz sine wave at 20 kHz offset)           IM performance         <-74 dB (typ)           Triggers         Trigger key, external, remote [LAN, GPIB, RS-232]           External polarity         Negative, positive           External delay time         10 ns to 40 s plus latency           External delay resolution         10 ns           Markers are defined in a segment during the waveform generation process or from the PSG           Marker polarity         Negative, positive           Number of markers         4           Multicarrier         Negative, positive           Number of orariers         Vegative, positive           Multicarrier         Vegative, positive           Number of orariers         0 Up to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)           Frequency offset (per carrier)         -40 MHz to +40 MHz           Power offset (per carrier)         -40 MHz to +40 MHz <tr< th=""><th>Clock</th><th></th></tr<>	Clock	
Accuracy         Same as timebase + 2-42 [in non-integer applications]           Reconstruction filter: [fixed]         50 MHz [used for all symbol rates]           Baseband spectral purity [full scale sine wave]         Image: Paper of Same of Sam	Sample rate	1 Hz to 100 MHz
Reconstruction filter: [fixed]         50 MHz [used for all symbol rates]           Baseband spectral purity [full scale sine wave]           Harmonic distortion         100 kHz to 2 MHz: < -65 dBc (typ)	Resolution	0.001 Hz
Baseband spectral purity [full scale sine wave]           Harmonic distortion         100 kHz to 2 MHz; < −65 dBc (typ)	Accuracy	Same as timebase +2 <sup>-42</sup> [in non-integer applications]
Harmonic distortion 100 kHz to 2 MHz: < -65 dBc (typ)  Phase noise < -127 dBc/Hz (typ) (baseband output of 10 MHz sine wave at 20 kHz offset)  IM performance < -74 dB (typ)  Triggers  Types Continuous, single, gated, segment advance  Source Trigger key, external, remote [LAN, GPIB, RS-232]  External polarity Negative, positive  External delay time 10 ns to 40 s plus latency  External delay resolution 10 ns  Markers are defined in a segment during the waveform generation process or from the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG  Murker polarity Negative, positive  Number of markers 4 4  Multicarrier  Number of carriers Up to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)  Frequency offset (per carrier) 40 MHz to +40 MHz  Power offset (per carrier) 0 dB to -40 dB  Modulation Types  PSK BPSK, CPSK, COPSK, T/4 DOPSK, 8PSK, 16PSK, D8PSK  QAM 4, 16, 32, 64, 128, 256  FSK Selectable phase deviation	Reconstruction filter: [fixed]	50 MHz [used for all symbol rates]
Phase noise < -127 dBc/Hz (typ) (baseband output of 10 MHz sine wave at 20 kHz offset)  M performance <-74 dB (typ)  Triggers  Types Continuous, single, gated, segment advance  Source Trigger key, external, remote [LAN, GPIB, RS-232]  External polarity Negative, positive  External delay time 10 ns to 40 s plus latency  External delay resolution 10 ns  Markers Markers are defined in a segment during the waveform generation process or from the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG Marker polarity Number of markers 4  Multicarrier  Number of carriers Up to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)  Frequency offset (per carrier) -40 MHz to +40 MHz  Power offset (per carrier) 1  Modulation 1  Types  PSK BPSK, OPSK, OPSK, T/4 DOPSK, 8PSK, 16PSK, D8PSK  QAM 4, 16, 32, 64, 128, 256  FSK Selectable PASE deviation	Baseband spectral purity [full scale sine wave]	
Triggers         Types       Continuous, single, gated, segment advance         Source       Trigger key, external, remote [LAN, GPIB, RS-232]         External polarity       Negative, positive         External delay time       10 ns to 40 s plus latency         External delay resolution       10 ns         Markers       Markers are defined in a segment during the waveform generation process or from the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG water polarity         Number of markers       4         Multicarrier       Vumber of carriers       Up to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)         Frequency offset (per carrier)       40 MHz to +40 MHz         Power offset (per carrier)       40 B to -40 dB         Modulation       Types         PSK       SPSK, OPSK, OPSK, π/4 DOPSK, 8PSK, 16PSK, D8PSK         QAM       4, 16, 32, 64, 128, 256         FSK       Selectable: 2, 4, 8, 16         MSK       Selectable phase deviation	Harmonic distortion	100 kHz to 2 MHz: < -65 dBc (typ)
Triggers           Types         Continuous, single, gated, segment advance           Source         Trigger key, external, remote [LAN, GPIB, RS-232]           External polarity         Negative, positive           External delay time         10 ns to 40 s plus latency           External delay resolution         10 ns           Markers         Markers are defined in a segment during the waveform generation process or from the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG           Marker polarity         Negative, positive           Number of markers         4           Multicarrier         Up to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)           Frequency offset (per carrier)         -40 MHz to +40 MHz           Power offset (per carrier)         -40 MHz to +40 dB           Modulation         Types           PSK         BPSK, QPSK, QPSK, m/4 DQPSK, 8PSK, 16PSK, D8PSK           QAM         4, 16, 32, 64, 128, 256           FSK         Selectable: 2, 4, 8, 16           MSK         Selectable phase deviation	Phase noise	< -127 dBc/Hz (typ) (baseband output of 10 MHz sine wave at 20 kHz offset)
Types Continuous, single, gated, segment advance  Source Trigger key, external, remote [LAN, GPIB, RS-232]  External polarity Negative, positive  External delay time 10 ns to 40 s plus latency  External delay resolution 10 ns  Markers Markers are defined in a segment during the waveform generation process or from the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG Marker polarity Negative, positive  Multicarrier  Number of carriers Vunber of carriers Up to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)  Frequency offset (per carrier) -40 MHz to +40 MHz Power offset (per carrier) 0 dB to -40 dB  Modulation Types  PSK BPSK, QPSK, QPSK, N/4 DQPSK, 8PSK, 16PSK, DBPSK  QAM 4, 16, 32, 64, 128, 256  FSK Selectable: 2, 4, 8, 16  MSK Selectable phase deviation	IM performance	< -74 dB (typ)
Source Trigger key, external, remote [LAN, GPIB, RS-232]  External polarity Negative, positive  External delay time 10 ns to 40 s plus latency  External delay resolution 10 ns  Markers are defined in a segment during the waveform generation process or from the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG front pane	Triggers	
External polarity  External delay time  External delay resolution  Markers  Markers are defined in a segment during the waveform generation process or from the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG  Marker polarity  Negative, positive  Number of markers  4  Multicarrier  Number of carriers  Up to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)  Frequency offset (per carrier)  Ad MHz to +40 MHz  Power offset (per carrier)  Od B to –40 dB  Modulation  Types  PSK  BPSK, QPSK, QPSK, N/4 DQPSK, R/4 DQPSK, BPSK, D8PSK  QAM  4, 16, 32, 64, 128, 256  FSK  Selectable: 2, 4, 8, 16  MSK  Selectable phase deviation	Types	Continuous, single, gated, segment advance
External delay time 10 ns to 40 s plus latency  External delay resolution 10 ns  Markers Markers are defined in a segment during the waveform generation process or from the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG Marker polarity Negative, positive  Number of markers 4  Multicarrier  Number of carriers Up to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)  Frequency offset (per carrier) -40 MHz to +40 MHz  Power offset (per carrier) 0 dB to -40 dB  Modulation Types  PSK BPSK, QPSK, QPSK, π/4 DQPSK, π/4 DQPSK, BPSK, 16PSK, D8PSK  QAM 4, 16, 32, 64, 128, 256  FSK Selectable: 2, 4, 8, 16  MSK Selectable phase deviation	Source	Trigger key, external, remote [LAN, GPIB, RS-232]
External delay resolution  Markers  Markers are defined in a segment during the waveform generation process or from the PSG front panel; a marker can also be tied to the RF blanking feature of the PSG  Marker polarity  Number of markers  Multicarrier  Number of carriers  Up to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)  Frequency offset (per carrier)  -40 MHz to +40 MHz  Power offset (per carrier)  0 dB to -40 dB  Modulation  Types  PSK  BPSK, QPSK, QPSK, QQPSK, \(\pi/4\) DQPSK, \(\pi/8\) PSK, \(\pi/8\) BPSK, \(\pi/8\) SPSK, \(\pi/8\) Selectable: 2, 4, 8, 16  FSK  Selectable phase deviation	External polarity	Negative, positive
MarkersMarkers are defined in a segment during the waveform generation process or from the PSG front panel; a marker can also be tied to the RF blanking feature of the PSGMarker polarityNegative, positiveNumber of markers4MulticarrierUp to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)Frequency offset (per carrier)-40 MHz to +40 MHzPower offset (per carrier)0 dB to -40 dBModulationTypesPSKBPSK, QPSK, QQPSK, π/4 DQPSK, 8PSK, 16PSK, D8PSKQAM4, 16, 32, 64, 128, 256FSKSelectable: 2, 4, 8, 16MSKSelectable phase deviation	External delay time	10 ns to 40 s plus latency
Marker polarity Number of markers  Multicarrier  Number of carriers  Number of servicers  Number of carriers  Addulation type)  Frequency offset (per carrier)  Add MHz to +40 MHz  OdB to -40 dB  Modulation  Types  PSK  BPSK, QPSK, QQPSK, N/4 DQPSK, 8PSK, 16PSK, D8PSK  QAM  4, 16, 32, 64, 128, 256  FSK  Selectable: 2, 4, 8, 16  MSK  Selectable phase deviation	External delay resolution	10 ns
Number of markers4MulticarrierUp to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)Frequency offset (per carrier)-40 MHz to +40 MHzPower offset (per carrier)0 dB to -40 dBModulationTypesPSKBPSK, QPSK, QPSK, π/4 DQPSK, 8PSK, 16PSK, D8PSKQAM4, 16, 32, 64, 128, 256FSKSelectable: 2, 4, 8, 16MSKSelectable phase deviation	Markers	
MulticarrierNumber of carriersUp to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)Frequency offset (per carrier)-40 MHz to +40 MHzPower offset (per carrier)0 dB to -40 dBModulationTypesPSKBPSK, QPSK, QPSK, π/4 DQPSK, 8PSK, 16PSK, D8PSKQAM4, 16, 32, 64, 128, 256FSKSelectable: 2, 4, 8, 16MSKSelectable phase deviation	Marker polarity	Negative, positive
Number of carriersUp to 100 (limited by a maximum bandwidth of 80 MHz depending on symbol rate and modulation type)Frequency offset (per carrier)-40 MHz to +40 MHzPower offset (per carrier)0 dB to -40 dBModulationTypesPSKBPSK, QPSK, QPSK, π/4 DQPSK, 8PSK, 16PSK, D8PSKQAM4, 16, 32, 64, 128, 256FSKSelectable: 2, 4, 8, 16MSKSelectable phase deviation	Number of markers	4
Frequency offset (per carrier)-40 MHz to +40 MHzPower offset (per carrier)0 dB to -40 dBModulationTypesPSKBPSK, QPSK, QPSK, DQPSK, π/4 DQPSK, 8PSK, 16PSK, D8PSKQAM4, 16, 32, 64, 128, 256FSKSelectable: 2, 4, 8, 16MSKSelectable phase deviation	Multicarrier	
Power offset (per carrier)0 dB to -40 dBModulationTypesPSKBPSK, QPSK, QQPSK, π/4 DQPSK, 8PSK, 16PSK, D8PSKQAM4, 16, 32, 64, 128, 256FSKSelectable: 2, 4, 8, 16MSKSelectable phase deviation	Number of carriers	
ModulationTypesPSKBPSK, QPSK, 0QPSK, π/4 DQPSK, 8PSK, 16PSK, D8PSKQAM4, 16, 32, 64, 128, 256FSKSelectable: 2, 4, 8, 16MSKSelectable phase deviation	Frequency offset (per carrier)	–40 MHz to +40 MHz
PSK         BPSK, QPSK, OQPSK, π/4 DQPSK, 8PSK, 16PSK, D8PSK           QAM         4, 16, 32, 64, 128, 256           FSK         Selectable: 2, 4, 8, 16           MSK         Selectable phase deviation	Power offset (per carrier)	0 dB to -40 dB
OAM 4, 16, 32, 64, 128, 256  FSK Selectable: 2, 4, 8, 16  MSK Selectable phase deviation	Modulation	Туреѕ
FSK Selectable: 2, 4, 8, 16  MSK Selectable phase deviation	PSK	BPSK, QPSK, OQPSK, π/4 DQPSK, 8PSK, 16PSK, D8PSK
MSK Selectable phase deviation	0AM	4, 16, 32, 64, 128, 256
	FSK	Selectable: 2, 4, 8, 16
Data Random only	MSK	Selectable phase deviation
	Data	Random only



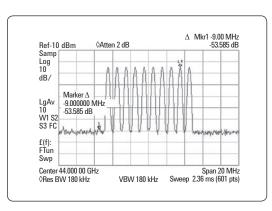
Four carriers with 64 QAM at 10 Msym/s with 20 MHz spacing (measured)

Multitone	
Number of tones	2 to 64, with selectable on/off state per tone
Frequency spacing	100 Hz to 80 MHz
Phase (per tone)	Fixed or random
Power offset (per tone)	0 to -40 dB

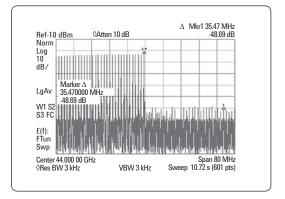




20 GHz multitone (measured)



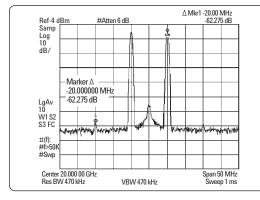
20 GHz image rejection (measured)

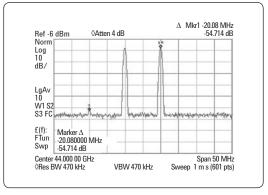


44 GHz multitone (measured)

44 GHz image rejection (measured)

Two-tone	
Frequency spacing	100 Hz to 80 MHz
Alignment	Left, centered, or right
IM distortion <sup>1</sup>	
250 kHz to 3.2 GHz	< -45 dBc (typ)
> 3.2 GHz to 20 GHz	< -55 dBc (typ)
> 20 to 40 GHz	< -50 dBc (typ)
> 40 to 44 GHz	< -45 dBc (typ)



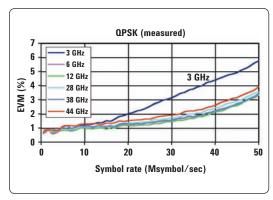


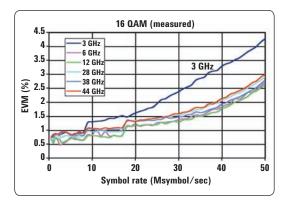
20 GHz two-tone (measured)

44 GHz two-tone (measured)

Internal baseband generator, real	-time mode (Option 602)	
Basic modulation types (custom format)		
PSK	BPSK, QPSK, OQPSK, π/4 DQPSK, 8PSK, 16PSK, D8F	PSK
MSK	User-defined phase offset from 0 to 100 $^{\circ}$	
QAM	4, 16, 32, 64, 128, 256	
FSK	Selectable: 2, 4, 8, 16 level symmetric, C4FM	
	User defined: Up to 16 custom deviation levels	
	Deviation resolution: 0.1 Hz	
	Symbol rate	Maximum deviation
	< 5 MHz	4 times symbol rate
	5 MHz to 50 MHz	20 MHz
User-defined I/Q	Custom map of 256 unique values	
Vector accuracy <sup>2</sup> (Formats: BPSK, QPSK, 16-256	QAM [ $\alpha = 0.3$ , root Nyquist filter, symbol rate 4 Msy	rm/s])
EVM (% RMS)	Spec	(typ)
≤ 20 GHz	< 1.2%	(< 0.8%)
> 20 to 32 GHz	< 1.3%	(< 0.9%)
> 32 to 44 GHz	< 1.4%	(< 0.9%)
Origin offset <sup>3</sup>		(typ)
250 kHz to 3.2 GHz		(-45 dBc)
3.2 to 44 GHz		(-50 dBc)

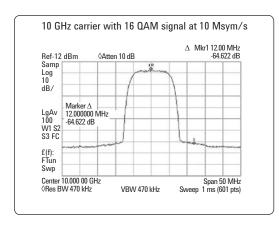
- 1. RF power ≤ −1 dBm (Option 520) or ≤ −3 dBm (Option 532, 544). When external inputs are used, vector accuracy is equivalent to internal performance after system calibration.
- 2. Valid after executing I/O calibration when instrument is maintained within ±5 °C of calibration temperature. RF power < 5 dBm (Option 520) or < 3 dBm (Option 532, 544). When external inputs are used, vector accuracy is equivalent to internal performance, after system calibration.
- 3. Valid after executing I/Q calibration when instrument is maintained at the calibration temperature.

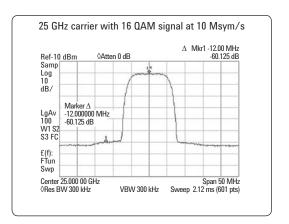




### EVM (measured)

FIR filter	
Selectable	Nyquist, root Nyquist, Gaussian, rectangular, $\alpha{:}~0$ to 1, $B_bT{:}~0.1$ to 1
Custom FIR	16-bit resolution, up to 64 symbols long, automatically resampled to 1024 coefficients (maximum) For > 32 to 64 symbol filter: symbol rate $\leq$ 12.5 MHz. For > 16 to 32 symbol filter: symbol rate $\leq$ 25 MHz. Internal filters switch to 16 tap when symbol rate is between 25 and 50 MHz
Symbol rate	
For external serial data	Adjustable from 1000 symbols/sec to a maximum symbol rate of 50 Mbits/sec ÷ (#bits/symbol)
For internally generated data	Adjustable from 1000 symbols/sec to 50 Msymbols/second and a maximum of 8 bits per symbol; modulation quality may be degraded at high symbol rates
Baseband reference frequency	
Input	ECL, CMOS, TTL compatible, 50 $\Omega$ AC coupled
Use	Data clock can be phase locked to an external reference.
Frame trigger delay control	
Range	0 to 1,048,575 bits
Resolution	1 bit
Data types	
Internally generated data	
Pseudo-random patterns	PN9, PN11, PN15, PN20, PN23
Repeating sequence	Any 4-bit sequence, other fixed patterns
Direct-pattern RAM [PRAM]	
Max size	64 Mb (each bit uses an entire sample space)
Use	Non-standard framing
User file	
Max size	6.4 Mb
Use	Continuous modulation or internally generated TDMA standard
Externally generated data	
Туре	Serial data
Inputs	Data, data (bit) clock, symbol sync
Rate	Accepts data rates $\pm 5\%$ of specified data rate
Internal burst shape control	
Rise/fall time range	Up to 30 bits, varies with standards and bit rates
Rise/fall delay range	0 to 63.5 bits, varies with standards and bit rates





Spectral re-growth (measured)

Туре	Real-time, continuously calculated,	Real-time, continuously calculated, and played using DSP	
Modes of operation	Standalone or digitally added to signal played by arbitrary waveform or real-time baseband generator		
Noise bandwidth	Arbitrary waveform mode:	50 kHz to 15 MHz	
	Real-time mode:	50 kHz to 80 MHz	
Crest factor	16 dB		
Randomness	Arbitrary waveform mode:	14, 15, 16, 17, 18, 19, or 20-bit pseudo-random waveform with fixed or random seed	
	Repetition period:	0.4 ms to 2 s (dependent on noise BW and waveform length combination)	
	Real-time mode:	89-bit pseudo-random generation	
	Repetition period:	3 x 10 <sup>9</sup> years	
Carrier-to-noise ratio formats	From front panel:	C/N	
Carrier-to-noise ratio formats	From Signal Studio Software:	C/N, Eb/No, Ec/No	
Remote programming			
Interfaces	GPIB (IEEE-488.2,1987) with listen and talk, RS-232, and 10BaseT LAN interface		
Control languages	SCPI version 1997.0; completely code compatible with previous PSG signal generator models:  • E8241A  • E8244A  • E8251A  • E8254C  • E8257C  The E8267D will emulate the applicable commands for the following Agilent signal generators, providing general compatibility with ATE systems:  • 8340-Series (8340/41B)  • 8360-Series (836xxB/L)  • 83700-Series (837xxB)  • 8662A/8663A		
IEEE-488 functions	• 8643A/8644B SH1, AH1, T6, TE0, L4, LE0, SR1, RL1, PP0, DC1, DT0, C0, E2		
Agilent IO libraries	Agilent's IO Library Suite ships with the E8267D to help you quickly establish an error-free connection between your PC and instruments – regardless of the vendor; it provides robust instrument control and works with the software development environment you choose		

Daau ua uiua ua austa	100 /120 VAC E0 /60 /400 Hz, or 220 /240 VAC E0 /60 Hz, /orthogoglically and analysis
Power requirements	100/120 VAC 50/60/400 Hz; or 220/240 VAC 50/60 Hz, (automatically selected); < 400 W typ, 650 W maximum
Operating temperature range	0 to 55 °C
Storage temperature range <sup>1</sup>	−40 to 70 °C
Altitude	0 to 4600 m (15,000 ft.)
Humidity	Relative humidity - type tested at 95%, +40°C (non-condensing)
Environmental testing	Samples of this product have been tested in accordance with the Agilent Environmental Test Manual and verified to be robust against the environmental stresses of storage, transportation, and end-use; those stresses include but are not limited to temperature, humidity, shock, vibration altitude, and power line conditions. Test methods are aligned with IEC 60068-2 and levels are similar to MIL-PRF-28800F Class 3. <sup>2</sup>
SO compliant	This family of signal generators is manufactured in an ISO-9001 registered facility in concurrence with Agilent's commitment to quality
EMC	Conforms to the immunity and emission requirements of IEC/EN 61326-1 including the conducted and radiated emission requirements of CISPR Pub 11/2003 Group 1 Class A.
Acoustic noise	Normal: 53 dBA (nom) Worst case: 62 dBA (nom) <sup>3</sup>
Storage	Memory is shared by instrument states, user data files, sweep list files, and waveform sequence. There is 14 MB of flash memory available in the E8267D PSG. With Option 009, there is an additional 8 GB of storage. Depending on how the memory is used, a maximum of 1000 instrument states can be saved.
Security	Display blanking Memory clearing functions (See Application Note, "Security Features of Agilent Technologies Signal Generators," Part Number E4400-90621) With Option 009, all user-written files are stored on an 8 GByte removable flash memory card.
Compatibility	Agilent 83550 Series millimeter heads and OML millimeter source modules Agilent 8757D scalar network analyzers Agilent EPM Series power meters
Self-test	Internal diagnostic routine tests most modules (including microcircuits) in a preset condition. For each module, if its node voltages are within acceptable limits, then the module "passes" the test
Veight	< 25 kg (54 lb.) net, < 33 kg (74 lb.) shipping
Dimensions	178 mm H x 426 mm W x 515 mm D (7" H x 16.8" W x 20.3" D)
Recommended calibration cycle	24 months

During storage below -20 °C, instrument states may be lost.
 As is the case with all signal generation equipment, phase noise specifications are not warranted in a vibrating environment.
 This is louder than typical Agilent equipment: 60 dBA (nom).

### **Input/Output Descriptions**

RF output	Output impedance 50 $\Omega$ (nom)
Option 520	Precision APC-3.5 male, or Type-N female with Option 1ED
Options 532 and 544	Precision 2.4 mm male; plus 2.4(f) - 2.4(f) mm and 2.4(f) - 2.9(f) mm adaptors
ALC input	Used for negative external detector leveling. Nominal input impedance 120 k $\Omega$ , damage level $\pm 15$ V
LF output	Outputs the internally generated LF source. Nominal output impedance 50 $\boldsymbol{\Omega}$
External input 1	Drives either AM, FM, or $\Phi M.$ Nominal input impedance 50 or 600 $\Omega,$ damage levels are 5 $V_{rms}$ and 10 $V_{peak}$
External input 2	Drives either AM, FM, or $\Phi M.$ Nominal input impedance 50 or 600 $\Omega,$ damage levels are 5 $V_{rms}$ and 10 $V_{peak}$
Pulse/trigger gate input	Accepts input signal for external fast pulse modulation. Also accepts external trigger pulse input for internal pulse modulation. Nominal impedance 50 $\Omega$ . Damage levels are 5 $V_{rms}$ and 10 $V_{peak}$
Pulse video out	Outputs a signal that follows the RF output in all pulse modes. TTL-level compatible, nominal source impedance 50 $\boldsymbol{\Omega}$
Pulse sync out	Outputs a synchronizing pulse, nominally 50 ns width, during internal and triggered pulse modulation. TTL-level compatible, nominal source impedance 50 $\Omega$
Data clock input	Accepts a data clock signal to synchronize serial data for use with internal baseband generator (Option 602) Maximum rate 50 MHz. Damage levels are $> +5.5$ V and $< -0.5$ V
Data input	Accepts serial data for use with internal baseband generator (Option 602); maximum rate 50 Mb/s; data must be valid on the falling edges of data clock (normal mode) or the symbol sync (symbol mode); damage levels are $> +5.5$ V and $< -0.5$ V
l input	Accepts an "I" input either for I/Q modulation or for wideband AM; nominal input impedance 50 or 600 $\Omega$ Damage levels are 1 $V_{rms}$ and 5 $V_{peak}$
Q input	Accepts a "Q" input for I/Q modulation; nominal input impedance 50 or 600 $\Omega.$ Damage levels are 1 $V_{rms}$ and 5 $V_{peak}$
Symbol sync input	Accepts symbol sync signal for use with internal baseband generator (Option 602); symbol sync might occur once per symbol or be a single, one bit wide pulse to synchronize the first bit of the first symbol; maximum rate 50 MHz; damage levels are > +5.5 V and < -0.5 V

<sup>1.</sup> Digital inputs and outputs are 3.3 V CMOS unless indicated otherwise. Inputs will accept 5 V CMOS, 3 V CMOS, or TTL voltage levels.

Auxiliary interface (dual mode)	Used for RS-232 serial communication and for master/slave source synchronization.
	(9-pin subminiature female connector). For master/slave operation, use Agilent part number 8120-8806 master/slave interface cable.
GPIB	Allows communication with compatible devices
LAN	Allows 10Base-T LAN communication
10 MHz input	Accepts a 10 MHz external reference (timebase) input. Nominal input impedance 50 $\Omega$ Damage levels $> +10\ dBm$
10 MHz output	Outputs internal or external reference signal. Nominal output impedance 50 $\Omega$ . Nominal output power +10 dBm
Sweep output (dual mode)	Supplies a voltage proportional to the RF power or frequency sweep ranging from 0 volts at the start of sweep to $\pm 10$ volts (nom) at the end of sweep, regardless of sweep width.
	During CW operation, supplies a voltage proportional to the output frequency, +10 volts (nom) corresponding to the maximum specified frequency.
	When connected to an Agilent 8757D scalar network analyzer (Option 007), generates a selectable number of equally spaced 1 $\mu$ s pulses (nom) across a ramp (analog) sweep. Number of pulses can be set from 101 to 1601 by remote control from the 8757D.
	Output impedance: < 1 $\Omega$ (nom), can drive 2 k $\Omega$ .
Stop sweep in/out	Open-collector, TTL-compatible input/output. In ramp sweep operation, provides low level (nominally 0 V during sweep retrace and bandcross intervals, and high level during the forward portion of the sweep. Sweep will stop when grounded externally; sweep will resume when allowed to go high.
Trigger output (dual mode)	Outputs a TTL signal. High at start of dwell, or when waiting for point trigger; low when dwell is over or point trigger is received. In ramp sweep mode, provides 1601 equally-spaced 1 $\mu$ s pulses (nom) across a ramp sweep. When using LF Out, provides 2 $\mu$ s pulse at start of LF sweep .
Trigger input	Accepts 3.3V CMOS signal for triggering point-to-point in manual sweep mode, or to trigger start of LF sweep. Damage levels $\geq$ +10 V or $\leq$ -4 V.
Source module interface	Agilent 83550 Series mm source modules: Provides bias, flatness correction and leveling connections.
	OML SxxMS-AG mm source modules: Provides power to the module and returns frequency multiplication information from the module.
Source settled	Provides an output trigger that indicates when the signal generator has settled to a new frequency or power level. High indicates source not settled, Low indicates source settled.
Z-axis blank/markers	During ramp sweep, supplies +5 V (nom) level during retrace and bandswitch intervals. Supplies –5 V (nom) level when the RF frequency is at a marker frequency.
10 MHz EFC	(Option UNX or UNY) Accepts an external DC voltage, ranging from $-5$ V to $+5$ V, for electronic frequency control (EFC) of the internal 10 MHz reference oscillator. This voltage inversely tunes the oscillator about its center frequency approximately $-0.07$ ppm/V. The nominal input impedance is greater than 1 M $\Omega$ .
.25 – 3.2 GHz coherent carrier output	Outputs RF signal modulated with FM or $\phi$ M but not I/Q, AM or pulse; nominal power 0 dBm; frequency range from 250 MHz to 3.2 GHz; not useful for output frequency > 3.2 GHz; damage levels 20 V <sub>DC</sub> and 13 dBm reverse RF power; (SMA female)
Baseband generator clock input	Accepts a sine or square wave PECL clock input with a frequency range of 200 to 400 MHz (resulting in sample rates of 50 MSa/s to 100 MSa/s); the recommended input level is approximately 1 Vpeak-to-peak for a square wave and 0 dBm to 6 dBm for a sine wave; allows the baseband generators of multiple signal generators to run off the same clock
Burst gate input	Accepts signal for gating burst power for use with internal baseband generator (Option 602); the burst gating is used for externally supplying data and clock information; the input signal must be synchronized with the external data input that will be output during the burst; the burst power envelope and modulated data are internally delayed and re-synchronized; the input signal must be CMOS high for normal burst RF power or CW RF output power and CMOS low for RF off; damage levels are $> +5.5 \text{ V}$ and $< -0.5 \text{ V}$
ALC Hold	This female BNC connector is a TTL-compatible input that controls ALC action with bursted I/Q signals from an arbitrary waveform generator (AWG). A high signal allows the ALC to track the RF signal and maintain constant RF output level as the I/Q inputs vary. A low input signal allows the ALC to be held for a brief time (< 1 s) and not track the RF signal. When driving the external I/Q inputs from an external AWG supplying a bursted waveform, the ALC Hold line should be driven from a marker output from the AWG that is high when the bursted signal is at the proper level and low when the bursted signal is not at the proper level. Damage levels are > 5.5 V and < $-0.5$ V.
1 GHz Ref Out	This female SMA connector (requires Option UNX or UNY) provides a 1 GHz output that is 100 times the frequency of the internal or external 10 MHz reference. The nominal output impedance is 50 $\Omega$ . When not in use, this connector must be terminated with a 50 $\Omega$ load.

<sup>1.</sup> Digital inputs and outputs are 3.3 V CMOS unless indicated otherwise. Inputs will accept 5 V CMOS, 3 V CMOS, or TTL voltage levels.

Coh carrier	This female SMA connector (requires Option UNT) outputs an RF signal that is phase coherent with the signal generator carrier. The coherent carrier outputs RF that is not modulated with AM, pulse, or I/Q modulation, but is modulated with FM or ΦM (when FM or ΦM are on).  The output power is nominally 0 dBm. The output frequency range is from 249.99900001 MHz to 3.2 GHz. This output is not useful for output frequencies > 3.2 GHz. If the RF output frequency is below 249.99900001 MHz, the coherent carrier output signal will have the following frequency:
	Frequency of coherent carrier = (1 GHz – Frequency of RF output)
	Damage levels are 20 $V_{\text{DC}}$ and +13 dBm reverse RF power. The nominal output impedance is 50 $\Omega.$
Event 1 output	In real-time mode, outputs a pattern or frame synchronization pulse for triggering or gating external equipment, for use with internal baseband generator (Option 602); may be set to start at the beginning of a pattern, frame, or timeslot and is adjustable to within $\pm$ one timeslot with one bit resolution; in arbitrary waveform mode, outputs a timing signal generated by marker 1
Event 2 output	In real-time mode, outputs a data enable signal for gating external equipment, for use with internal baseband generator (Option 602); applicable when external data is clocked into internally generated timeslots; data is enabled when signal is low; in arbitrary waveform mode, outputs a timing signal generated by marker 2
I and $\Omega$ outputs	Outputs the analog I/Q modulation signals from the internal baseband generator; nominal output impedance 50 $\Omega$ , DC-coupled; damage levels $\pm 3.5$ V
I and $\Omega$ outputs	Outputs the complement of the I and Q signals for differential applications; nominal output impedance 50 $\Omega$ , DC-coupled; damage levels $\pm 3.5$ V
Pattern trigger input	Accepts signal to trigger internal pattern or frame generator to start single pattern output, for use with internal baseband generator (Option 602); minimum pulse width 100 ns; damage levels are $> +5.5 \text{ V}$ and $< -0.5 \text{ V}$
Wideband I and Q inputs	Direct differential high-bandwidth analog inputs to $I/Q$ modulator in 3.2 to 44 GHz range and useable for carriers < 3.2 GHz; not calibrated; 0 dBm maximum; (Option 016 only). SMA female connectors.
Removable flash memory drive	Accepts 8 GB compact flash memory card for optional non-volatile memory (Option 009 only); all user information (save/recall settings, flatness files, presets, etc.) is stored on removable memory card when Option 009 is installed
Auxiliary I/O connecto	r (37-pin) used with Option 602
Alternate power input	Accepts CMOS signal for synchronization of external data and alternate power signal timing; damage levels are $> +8$ V and $< -4$ V
Event 3 output	In arbitrary waveform mode, outputs a timing signal generated by marker 3; damage levels $>$ +8 V and $<$ 4 V
Event 4 output	In arbitrary waveform mode, outputs a timing signal generated by marker 4; damage levels $>$ +8 V and $<$ 4 V
Symbol sync output	Outputs CMOS symbol clock for symbol synchronization, one data clock period wide

### Options, Accessories, and Related Products

Model/option	Description
E8267D-520	Frequency range from 250 kHz to 20 GHz
E8267D-532	Frequency range from 250 kHz to 31.8 GHz
E8267D-544	Frequency range from 250 kHz to 44 GHz
E8267D-602	Internal baseband generator, 64 MSa memory
E8267D-003	Digital output connectivity with N5102A
E8267D-004	Digital input connectivity with N5102A
E8267D-007	Analog ramp sweep
E8267D-009	8 GB removable flash memory
E8267D-016	Wideband external I/Q inputs
E8267D-403	Calibrated AWGN
E8267D-409	Global positioning system (GPS) personality
E8267D-422	Scenario generator for GPS personality
E8267D-UNX	Ultra low phase noise

ENEASTO_LINT         Enhanced ultra low phase noise           ENEASTO_LINT         AM, FM, phase noise           ENEASTO_LINU         Pulse modulation           ENEASTO_LICO         Type-N (1) RF output connector           ENEASTO_LICO         Type-N (1) RF output connector           ENEASTO_LICO         Improved harmonics below 2 GHz           ENEASTO_LICO         Front handle kt           ENEASTO_LICO         Rackmount flange lat           ENEASTO_LICO         Rackmount flange and front handle kt           ENEASTO_LARI         ANISTEAU-1 compliant calibration with test data           ENEASTO_LARI         ANISTEAU-1 compliant calibration with test data           ENEASTO_LARI         Printed copy of the English documentation set           ENEASTO_LARI         Printed copy of the English documentation set           ENEASTO_LARI         Signal Studio for jitter injection           NYBOR         Signal Studio for jitter injection           NYBOR         Signal St		
E8287D-UNUN         Pulse modulation           E8287D-LEN         Narrow pulse modulation           E8287D-1EH         Improved harmonics below 2 GHz           E8287D-1EM         Moves all front panel connectors to the rear panel           E8287D-1CM         Front handle kit           E8287D-1CM         Backmount flange and front handle kit           E8287D-1CP         Rackmount flange and front handle kit           E8287D-MS         Commercial calibration certificate and test data           E8287D-ASJ         ANS 2540-1 compliant calibration with test data           E8287D-ASJ         COMERCIAL calibration with test data           E8287D-ASJ         CD-ROM containing the English documentation set           E8287D-BR         Printed copy of the English documentation set           E8287D-BR         Printed copy of the English documentation set           E8287D-SPQ         Opanitic sequencing capability           Application software         Signal Studio for jitter injection           E8287D-SPQ         Signal Studio for 38PP CDMA           N7600B         Signal Studio for 38PP CDMA           N760B         Signal Studio for 38PP CDMA           N760BA         Signal Studio for situation for Mileston           N760BA         Signal Studio for ROX-11 WLAN           N760BA         Signal Studio fo	E8267D-UNY	Enhanced ultra low phase noise
EB2670-UNW         Narrow pulse modulation           EB2670-IED         Type-N (I) Fix output connector           EB2670-IEM         Moves all front panel connectors to the rear panel           EB2670-ICN         Front handle kit           EB2670-ICN         Front handle kit           EB2670-ICP         Rackmount flange and front handle kit           EB2670-ICP         Rackmount flange and front handle kit           EB2670-ICR         Commercial calibration certificate and test data           EB2670-IAS         Commercial calibration with test data           EB2670-IAT         ISO 17025 accredited calibration with test data           EB2670-DCD1         CD-ROM containing the English documentation set           EB2670-DBW         Printed copy of the English documentation set           EB2670-DBW         Printed copy of the assembly-level service guide           EB2670-SP2         Signal Studio for jitter injection           N7601B         S		·
E8287D-1ED         Type-N (f) RF output connector           E8287D-1EH         Improved harmonics below 2 GHz           E8287D-1CN         Front handle kit           E8287D-1CM         Rackmount flange kit           E8287D-1CM         Rackmount flange and front handle kit           E8287D-1CP         Rackmount flange and front handle kit           E8287D-1CB         Commercial calibration certificate and test data           E8287D-1AG         ANSI 2540-1 compliant calibration with test data           E8287D-1AT         150 17625 accredited calibration with test data           E8287D-1AT         150 17625 accredited calibration with test data           E8287D-1ABA         Printed copy of the Eaglish documentation set           E8287D-1BB         Signal Studio for ill tessambly-levels serice guide           E8287D-1BB         Signal Studio for S	E8267D-UNU	
E8287D-1EH         Improved harmonics below 2 GHz           E8287D-1EM         Mows all front panel connectors to the rear panel           E8287D-1CN         Front handle kit           E8287D-1CP         Rackmount flange kit           E8287D-1CP         Rackmount flange and front thandle kit           E8287D-1CP         ANSI 2540-1 compliant calibration with test data           E8287D-1CP         Commercial calibration on with test data           E8287D-1CP         Printed copy of the assembly-level service guide           E8287D-1CP         Printed copy of the assembly-level service guide           E8287D-1CP         Printed copy of the English documentation set           E8287D-1CP         Signal Studio for 3GPP W-CDMA FDD           N7600B         Signal Studio for 3GPP W-CDMA FDD           N7601D         Signal Studio for GSMV-Edge	E8267D-UNW	Narrow pulse modulation
E8287D-1EM         Moves all front panel connectors to the rear panel           E8267D-1CN         Front handle kit           E8267D-1CP         Rackmount flange kit           E8267D-1CP         Rackmount flange and front handle kit           E8267D-UNS         Commercial calibration certificate and test data           E8267D-ASJ         ANSI 2540-1 compliant calibration with test data           E8267D-CD1         CD-ROM containing the English documentation set           E8267D-DED         Printed copy of the English documentation set           E8267D-BW         Printed copy of the assembly-level service guide           E8267D-BW         Printed copy of the assembly-level service guide           E8267D-SP2         Dynamic sequencing capability           Application software         Signal Studio for jitter injection           N760BB         Signal Studio for 3GPP VM-CDMA FDD           N760BB         Signal Studio for SBPP CDMA           N760BB         Signal Studio for SBM-Edge           N761BB         Signal Studio for SBM-Edge           N761BB         Signal Studio for sBM Edge           N761BB         Signal Studio for sBM Edge	E8267D-1ED	Type-N (f) RF output connector
E8267D-1CN         Front handle kit           E8267D-1CHM         Rackmount flange kit           E8267D-1CP         Rackmount flange and front handle kit           E8267D-UK6         Commercial calibration certificate and test data           E8267D-ASJ         ANSI 2540 - Compliant calibration with test data           E8267D-AT         ISO 17025 accredited calibration with test data           E8267D-CD1         CD-ROM containing the English documentation set           E8267D-ABA         Printed copy of the English documentation set           E8267D-BBW         Printed copy of the assembly-level service guide           E8267D-SP1         Opnamic sequencing capability           Application software         E8267D-SP1         Signal Studio for jitter injection           N7600B         Signal Studio for 36PP V-CDMA FDD         Printed Copy of the Sea Sea Sea Sea Sea Sea Sea Sea Sea Se	E8267D-1EH	Improved harmonics below 2 GHz
E82E7D-1 CM         Rackmount flange kit           E82E7D-10P         Rackmount flange and front handle kit           E82E7D-URG         Commercial calibration certificate and test data           E82E7D-NaG         ANSI 2540-1 compliant calibration with test data           E82E7D-1A7         ISO 17025 accredited calibration with test data           E82E7D-DCD1         CD-ROM containing the English documentation set           E82E7D-ABA         Printed copy of the Rassembly-level service guide           E82E7D-SBW         Printed copy of the sasembly-level service guide           E82E7D-SP2         Dynamic sequencing capability           Application software         Fear of Saper V-CDMA           E82E7D-SP1         Signal Studio for 3GPP V-CDMA FDD           N7601B         Signal Studio for 3GPP2 CDMA           N7601B         Signal Studio for 3GPP2 CDMA           N7602B         Signal Studio for 8DLetooth®           N7603A         Signal Studio for 8DLetooth®           N7604B         Signal Studio for 802.15 CPDMA Mobile ViMax           N7615B         Signal Studio for 802.15 CPDMA Mobile ViMax           N7617B         Signal Studio for multiband OFDM UWB           N7621B         Signal Studio for pulse building           N7621B         Signal Studio for pulse building           N7622B <t< th=""><th>E8267D-1EM</th><th>Moves all front panel connectors to the rear panel</th></t<>	E8267D-1EM	Moves all front panel connectors to the rear panel
E8287D-1CP         Rackmount flange and front handle kit           E8287D-UKS         Commercial calibration certificate and test data           E8287D-A6AJ         ANSI 2540-1 compliant calibration with test data           E8287D-A7         ISO 17025 accredited calibration with test data           E8287D-DCDI         CD-ROM containing the English documentation set           E8287D-BADA         Printed copy of the assembly-level service guide           E8287D-BPW         Dynamic sequencing capability           Application software         B8287D-SP1           E8287D-SP1         Signal Studio for jitter injection           N7601B         Signal Studio for 3GPP2 CDMA           N7601B         Signal Studio for 3GPP2 CDMA           N7601B         Signal Studio for 3GPP2 CDMA           N7602B         Signal Studio for GSMV-Edge           N7603B         Signal Studio for Blustooth®           N7603B         Signal Studio for Blustooth®           N7603B         Signal Studio for 802.16-2004 Fixed Wilkax™           N7613A         Signal Studio for 802.16-2004 Fixed Wilkax™           N7613B         Signal Studio for multiband OFDM UWB           N7619B         Signal Studio for pulse building           N7621B         Signal Studio for julie building           N7622B         Signal Studio for digital vid	E8267D-1CN	Front handle kit
E8287D-UK6         Commercial calibration certificate and test data           B8287D-AGJ         ANSI Z540-1 compilant calibration with test data           E8287D-101         CD-ROM containing the English documentation set           E8287D-ABA         Printed copy of the English documentation set           E8287D-DBW         Printed copy of the assembly-level service guide           E8287D-SP2         Dynamic sequencing capability           Application software           E8287D-SP1         Signal Studio for jitter injection           N7600B         Signal Studio for 3GPP W-CDMA FDD           N7601B         Signal Studio for 3GPP CDMA           N7602B         Signal Studio for GSM/Edge           N7602B         Signal Studio for GSM/Edge           N7603A         Signal Studio for GSM/Edge           N7604B         Signal Studio for GSM.Edge           N7605B         Signal Studio for GSM.Edge           N7606B         Signal Studio for GSM.Edge           N7607B         Signal Studio for GSD.11 WLAN           N7608B         Signal Studio for B02.16 2004 Fixed Wilmax.           N7619A         Signal Studio for multitone distortion testing           N7617B         Signal Studio for multitone distortion testing           N7621B         Signal Studio for object to object to object to object to objec	E8267D-1CM	Rackmount flange kit
E8267D-A6J         ANSI Z540-1 compliant calibration with test data           E8267D-L07         ISD 17025 accredited calibration with test data           E8267D-CD1         CD-ROM containing the English documentation set           E8267D-ABA         Printed copy of the English documentation set           E8267D-BW         Printed copy of the assembly-level service guide           E8267D-SP2         Dynamic sequencing capability           Application software           E8267D-SP1         Signal Studio for JGPP W-CDMA FDD           N7600B         Signal Studio for 3GPP2 CDMA           N7601B         Signal Studio for GBM-Edge           N7602B         Signal Studio for BMC4dge           N7602B         Signal Studio for BMC4dge           N7609B         Signal Studio for BM2-16-2004 Fixed WiMax™           N7613A         Signal Studio for 802.16-2004 Fixed WiMax™           N7615B         Signal Studio for 802.11 WLAN           N7617B         Signal Studio for 802.11 WLAN           N7619A         Signal Studio for BM2 History           N762B         Signal Studio for Julse building           N762B         Signal Studio for digital video           N762B         Signal Studio for digital video           N762B         Signal Studio for digital video           N762B	E8267D-1CP	Rackmount flange and front handle kit
E8267D-1A7         ISO 17025 accredited calibration with test data           E8267D-CD1         CD-ROM containing the English documentation set           E8267D-BBA         Printed copy of the English documentation set           E8267D-SP2         Printed copy of the assembly-level service guide           E8267D-SP2         Dynamic sequencing capability           Application software           E8267D-SP1         Signal Studio for JGPP W-CDMA FDD           N7600B         Signal Studio for 3GPP W-CDMA FDD           N7601B         Signal Studio for GSPP CDMA           N7602B         Signal Studio for GSM/Edge           N7605A         Signal Studio for Bluetooth®           N7605B         Signal Studio for Bluetooth®           N7617B         Signal Studio for Bluetooth Flow           N7617B         Signal Studio for Bluetooth Flow           N7621B         Signal Studio for Juletooth Flow           N7622B         Signal Studio for Juletooth Flow           N7621B         Signal Studio for Glow Flo	E8267D-UK6	Commercial calibration certificate and test data
E8267D-CD1         CD-ROM containing the English documentation set           E8267D-ABA         Printed copy of the English documentation set           E8267D-DBW         Printed copy of the assembly-level service guide           E8267D-SP2         Dynamic sequencing capability           Application software           E8267D-SP1         Signal Studio for jitter injection           N7600B         Signal Studio for 3GPP V-CDMA FDD           N7601B         Signal Studio for 3GPP 2 CDMA           N7602B         Signal Studio for BULLOTAM           N7603A         Signal Studio for BULLOTAM           N7613A         Signal Studio for BULLOTAM           N7615B         Signal Studio for BULLOTAM           N7617B         Signal Studio for BULLOTAM           N7617B         Signal Studio for BULLOTAM           N762B         Signal Studio for BULLOTAM           N762B         Signal Studio for Jullotam distortion testing           N762B         Signal Studio for Jullotam           N762B         Signal Studio for SULLOTAM           N762B <th>E8267D-A6J</th> <th>ANSI Z540-1 compliant calibration with test data</th>	E8267D-A6J	ANSI Z540-1 compliant calibration with test data
E8267D-ABAA         Printed copy of the assembly-level service guide           E8267D-SP2         bynamic sequencing capability           Application software         Facebro Sp2           E8267D-SP1         Signal Studio for jitter injection           N7600B         Signal Studio for 3GPP W-CDMA FDD           N7601B         Signal Studio for 3GPP CDMA           N7602B         Signal Studio for SMP/Edge           N7604B         Signal Studio for GSM/Edge           N7605B         Signal Studio for GSM/Edge           N7606B         Signal Studio for GSM/Edge           N7607B         Signal Studio for BNS           N7613A         Signal Studio for BN2 In GAMA Mobile WiMax           N7615B         Signal Studio for 802.16 QFDMA Mobile WiMax           N7617B         Signal Studio for 802.11 WLAN           N7617B         Signal Studio for multiband QFDM UWB           N7621B         Signal Studio for multiband QFDM UWB           N7621B         Signal Studio for multiband QFDM UWB           N7622B         Signal Studio for in Intitione distortion testing           N7622B         Signal Studio for down Unitione distortion testing           N7622B         Signal Studio for 3GPP LTE-FDD           N626B         Signal Studio for 3GPP LTE-FDD           N627B         Sign	E8267D-1A7	ISO 17025 accredited calibration with test data
E8267D-0BW         Printed copy of the assembly-level service guide           E8267D-SP2         Dynamic sequencing capability           Application software         February 1000           E8267D-SP1         Signal Studio for jitter injection           N7601B         Signal Studio for 3GPP W-CDMA FDD           N7601B         Signal Studio for GSM/Edge           N7602B         Signal Studio for Buetooth®           N7608A         Signal Studio for Buetooth®           N7609B         Signal Studio for Buetooth®           N7613A         Signal Studio for Buetooth®           N7615B         Signal Studio for 802.16 OPDMA Mobile WiMax           N7617B         Signal Studio for 802.11 WLAN           N7619A         Signal Studio for 802.11 WLAN           N7621B         Signal Studio for multitone distortion testing           N7621B         Signal Studio for multitone distortion testing           N7621B         Signal Studio for digital video           N7621B         Signal Studio for digital video           N7621B         Signal Studio for 3GPP LTE-TDD           N7622B         Signal Studio for 3GPP LTE-TDD           N7621B         Signal Studio for 3GPP LTE-TDD           N6171A         Mat Lab software           E8267D-H1S         1 GHz external frequency reference	E8267D-CD1	CD-ROM containing the English documentation set
E8267D-SP2         Dynamic sequencing capability           Application software         E8267D-SP1         Signal Studio for jitter injection           N7600B         Signal Studio for 3GPP W-CDMA FDD           N7601B         Signal Studio for 3GPP2 CDMA           N7602B         Signal Studio for 3GPP2 CDMA           N7606A         Signal Studio for BM2-E6           N7609B         Signal Studio for BM2-E-2004 Fixed WiMax™           N7613A         Signal Studio for 802.16-2004 Fixed WiMax™           N7617B         Signal Studio for 802.16 OFDMA Mobile WiMax           N7617B         Signal Studio for 802.16 OFDMA Mobile WiMax           N7617B         Signal Studio for 802.11 WLAN           N7620B         Signal Studio for multiband OFDM UWB           N7620B         Signal Studio for multiband OFDM UWB           N7621B         Signal Studio for multiband distortion testing           N7622B         Signal Studio for digital video           N7623B         Signal Studio for digital video           N7624B         Signal Studio for 3GPP LTE-FDD           N7625B         Signal Studio for 3GPP LTE-FDD           N7627B         Signal Studio for phase coherency and improved phase stability < 250 MHz	E8267D-ABA	Printed copy of the English documentation set
Application software           E8267D-SP1         Signal Studio for jitter injection           N7600B         Signal Studio for 3GPP W-CDMA FDD           N7601B         Signal Studio for GSMYEdge           N7602B         Signal Studio for GSMYEdge           N7606A         Signal Studio for Bluetooth®           N7609B         Signal Studio for 80S           N7613A         Signal Studio for 802.16-2004 Fixed WiMax™           N7615B         Signal Studio for 802.16 DFDMA Mobile WiMax           N7617B         Signal Studio for 802.11 WLAN           N762B         Signal Studio for 802.11 WLAN           N762B         Signal Studio for multiband OFDM UWB           N762B         Signal Studio for multiband OFDM UWB           N762B         Signal Studio for multiband OFDM UWB           N762B         Signal Studio for opluse building           N762B         Signal Studio for oligital video           N762B         Signal Studio for 3GPP LTE-FDD           N762B         Signal Studio for 3GPP LTE-FDD           N762B         Signal Studio for 3GPP LTE-FDD           N762B         Signal Studio for 3GPP LTE-TDD           N762B         Signal Studio for plase coherency and improved phase stability < 250 MHz           E826TD-H1S         1 GHz external frequency reference input	E8267D-0BW	Printed copy of the assembly-level service guide
E267D-SP1         Signal Studio for jitter injection           N7600B         Signal Studio for 3GPP W-CDMA FDD           N7601B         Signal Studio for 3GPP2 CDMA           N7602B         Signal Studio for GMY-Edge           N7609A         Signal Studio for GMS           N7613A         Signal Studio for 802.16-2004 Fixed WiMax™           N7615B         Signal Studio for 802.16 OFDMA Mobile WiMax           N7617B         Signal Studio for 802.11 VLAN           N7619A         Signal Studio for BUD WB           N762B         Signal Studio for multiband OFDM UWB           N762B         Signal Studio for pulse building           N762B         Signal Studio for digital video           N762B         Signal Studio for digital video           N762B         Signal Studio for 3GPP LTE-TDD           N762B         Signal Studio for digital video           N	E8267D-SP2	Dynamic sequencing capability
N7600B         Signal Studio for 3GPP W-CDMA           N7601B         Signal Studio for 3GPP2 CDMA           N7602B         Signal Studio for GSM/Edge           N7606A         Signal Studio for Bluetooth®           N7609B         Signal Studio for 802.16-2004 Fixed WiMax™           N7613A         Signal Studio for 802.16-2004 Fixed WiMax™           N7617B         Signal Studio for 802.16 DFDMA Mobile WiMax           N7617B         Signal Studio for 802.11 WLAN           N7619A         Signal Studio for multiband OFDM UWB           N7620B         Signal Studio for pulse building           N7621B         Signal Studio for multitone distortion testing           N7622B         Signal Studio for digital video           N7623B         Signal Studio for digital video           N7623B         Signal Studio for digital video           N7624B         Signal Studio for 3GPP LTE-FDD           N624B         Signal Studio for 3GPP LTE-FDD           N627B         Signal Studio for 3GPP LTE-TDD           N627B         Signal Studio for 3GPP LTE-FDD           N627B         Signal Studio for 3GPP LTE-FDD           Customized product solutions         Customized product solutions           E8267D-H1S         1 GHz external frequency reference input           E8267D-H1G <th< th=""><th>Application software</th><th></th></th<>	Application software	
N7601B         Signal Studio for 3GPP2 CDMA           N7602B         Signal Studio for GSM/Edge           N7608A         Signal Studio for Bluetooth®           N7609B         Signal Studio for GNSS           N7613A         Signal Studio for 802.16-2004 Fixed WiMax™           N7615B         Signal Studio for 802.16 OFDMA Mobile WiMax           N7617B         Signal Studio for 802.11 WLAN           N7619A         Signal Studio for multiband OFDM UWB           N7620B         Signal Studio for multitone distortion testing           N7621B         Signal Studio for multitone distortion testing           N7622A         Signal Studio for digital video           N7623B         Signal Studio for 3GPP LTE-FDD           N7625B         Signal Studio for 3GPP LTE-FDD           N625B         Signal Studio for 3GPP LTE-TDD           N6171A         MATLAB software           Customized product solutions         MATLAB software           E8267D-H1S         1 GHz external frequency reference input           E8267D-H1G         Connections for phase coherency > 250 MHz ¹           E8267D-H2C         Connections for phase coherency > 250 MHz ¹           E8267D-H3         Wideband modulation below 3.2 GHz           Accessories         Uideband modulation below 3.2 GHz           B19-0427 <th>E8267D-SP1</th> <th>Signal Studio for jitter injection</th>	E8267D-SP1	Signal Studio for jitter injection
N7602B         Signal Studio for GSM/Edge           N7606A         Signal Studio for Bluetooth®           N7609B         Signal Studio for GNSS           N7613A         Signal Studio for 802.16-2004 Fixed WiMax™           N7615B         Signal Studio for 802.16 OFDMA Mobile WiMax           N7617B         Signal Studio for 802.11 WLAN           N7619A         Signal Studio for multiband OFDM UWB           N7620B         Signal Studio for multiband OFDM UWB           N7621B         Signal Studio for multitone distortion testing           N7622A         Signal Studio for digital video           N7623B         Signal Studio for digital video           N7624B         Signal Studio for 3GPP LTE-FDD           N7625B         Signal Studio for 3GPP LTE-TDD           N6171A         MATLAB software           Customized product solutions           E8267D-H1S         1 GHz external frequency reference input           E8267D-H1G         Connections for phase coherency and improved phase stability < 250 MHz           E8267D-H1B         Wideband modulation below 3.2 GHz           Accessories         Using Studio of or phase coherency > 250 MHz 1           819-0427         8 GByte compact flash memory card           810-8806         Master/slave interface cable           N5102A <th>N7600B</th> <th>Signal Studio for 3GPP W-CDMA FDD</th>	N7600B	Signal Studio for 3GPP W-CDMA FDD
N7606A         Signal Studio for Bluetooth®           N7609B         Signal Studio for GNSS           N7613A         Signal Studio for 802.16-2004 Fixed WiMax™           N7615B         Signal Studio for 802.16 0FDMA Mobile WiMax           N7617B         Signal Studio for 802.11 WLAN           N7619A         Signal Studio for multiband 0FDM UWB           N7620B         Signal Studio for pulse building           N7621B         Signal Studio for multitone distortion testing           N7622A         Signal Studio for digital video           N7623B         Signal Studio for 3GPP LTE-FDD           N7624B         Signal Studio for 3GPP LTE-FDD           N7625B         Signal Studio for 3GPP LTE-TDD           N6171A         MATLAB software           E8267D-H1S         1 GHz external frequency reference input           E8267D-H1G         Connections for phase coherency and improved phase stability < 250 MHz	N7601B	Signal Studio for 3GPP2 CDMA
N7609B         Signal Studio for GNSS           N7613A         Signal Studio for 802.16-2004 Fixed WiMax™           N7615B         Signal Studio for 802.16 OFDMA Mobile WiMax           N7617B         Signal Studio for 802.11 WLAN           N7619A         Signal Studio for pulse building           N7620B         Signal Studio for pulse building           N7621B         Signal Studio for multitone distortion testing           N7622A         Signal Studio for digital video           N7623B         Signal Studio for 3GPP LTE-FDD           N7624B         Signal Studio for 3GPP LTE-FDD           N7627B         Signal Studio for 3GPP LTE-TDD           N6171A         MATLAB software           Customized product solutions         Signal Studio for phase coherency and improved phase stability < 250 MHz	N7602B	Signal Studio for GSM/Edge
N7613A         Signal Studio for 802.16-2004 Fixed WiMax™           N7615B         Signal Studio for 802.16 OFDMA Mobile WiMax           N7617B         Signal Studio for 802.11 WLAN           N7619A         Signal Studio for multiband OFDM UWB           N7620B         Signal Studio for pulse building           N7621B         Signal Studio for multitone distortion testing           N7622A         Signal Studio Toolkit           N7623B         Signal Studio for digital video           N7624B         Signal Studio for 3GPP LTE-FDD           N7625B         Signal Studio for 3GPP LTE-TDD           N6171A         MATLAB software           Customized product solutions         E8267D-H1S           E8267D-H1S         1 GHz external frequency reference input           E8267D-H2C         Connections for phase coherency and improved phase stability < 250 MHz	N7606A	Signal Studio for <i>Bluetooth</i> ®
N7615B         Signal Studio for 802.16 OFDMA Mobile WiMax           N7617B         Signal Studio for 802.11 WLAN           N7619A         Signal Studio for multiband OFDM UWB           N7620B         Signal Studio for pulse building           N7621B         Signal Studio for multitone distortion testing           N7622A         Signal Studio Toolkit           N7623B         Signal Studio for digital video           N7624B         Signal Studio for 3GPP LTE-FDD           N7625B         Signal Studio for 3GPP LTE-TDD           N6171A         MATLAB software           Customized product solutions           E8267D-H1S         1 GHz external frequency reference input           E8267D-H1G         Connections for phase coherency and improved phase stability < 250 MHz           E8267D-H2C         Connections for phase coherency > 250 MHz \frac{1}{2}           E8267D-H1B         Wideband modulation below 3.2 GHz           Accessories           U3035P         Distribution network (lock box) \frac{1}{1}           1819-0427         8 GByte compact flash memory card           8120-8806         Master/slave interface cable           N5102A         Digital signal interface module	N7609B	Signal Studio for GNSS
N7617B         Signal Studio for 802.11 WLAN           N7619A         Signal Studio for multiband OFDM UWB           N7620B         Signal Studio for pulse building           N7621B         Signal Studio for multitone distortion testing           N7622A         Signal Studio Toolkit           N7623B         Signal Studio for 3GPP LTE-FDD           N7624B         Signal Studio for 3GPP LTE-FDD           N7625B         Signal Studio for 3GPP LTE-TDD           N6171A         MATLAB software           Customized product solutions           E8267D-H1S         1 GHz external frequency reference input           E8267D-H1G         Connections for phase coherency and improved phase stability < 250 MHz	N7613A	Signal Studio for 802.16-2004 Fixed WiMax™
N7619A         Signal Studio for multiband OFDM UWB           N7620B         Signal Studio for pulse building           N7621B         Signal Studio for multitone distortion testing           N7622A         Signal Studio Toolkit           N7623B         Signal Studio for digital video           N7624B         Signal Studio for 3GPP LTE-FDD           N7625B         Signal Studio for 3GPP LTE-TDD           N6171A         MATLAB software           Customized product solutions           E8267D-H1S         1 GHz external frequency reference input           E8267D-H1G         Connections for phase coherency and improved phase stability < 250 MHz	N7615B	Signal Studio for 802.16 OFDMA Mobile WiMax
N7620B         Signal Studio for pulse building           N7621B         Signal Studio for multitone distortion testing           N7622A         Signal Studio Toolkit           N7623B         Signal Studio for digital video           N7624B         Signal Studio for 3GPP LTE-FDD           N7625B         Signal Studio for 3GPP LTE-TDD           N6171A         MATLAB software           Customized product solutions           E8267D-H1S         1 GHz external frequency reference input           E8267D-H1G         Connections for phase coherency and improved phase stability < 250 MHz	N7617B	Signal Studio for 802.11 WLAN
N7621B Signal Studio for multitone distortion testing  N7622A Signal Studio Toolkit  N7623B Signal Studio for digital video  N7624B Signal Studio for 3GPP LTE-FDD  N7625B Signal Studio for 3GPP LTE-TDD  N6171A MATLAB software  Customized product solutions  E8267D-H1S 1 GHz external frequency reference input  E8267D-H1G Connections for phase coherency and improved phase stability < 250 MHz  E8267D-H18 Wideband modulation below 3.2 GHz  Accessories  U3035P Distribution network (lock box) 1  1819-0427 8 GByte compact flash memory card  8120-8806 Master/slave interface cable  N5102A Digital signal interface module	N7619A	Signal Studio for multiband OFDM UWB
N7622A Signal Studio Toolkit  N7623B Signal Studio for digital video N7624B Signal Studio for 3GPP LTE-FDD N7625B Signal Studio for 3GPP LTE-TDD N6171A MATLAB software  Customized product solutions  E8267D-H1S 1 GHz external frequency reference input E8267D-H1G Connections for phase coherency and improved phase stability < 250 MHz E8267D-HCC Connections for phase coherency > 250 MHz 1 E8267D-H18 Wideband modulation below 3.2 GHz  Accessories  U3035P Distribution network (lock box) 1 1819-0427 8 GByte compact flash memory card 8120-8806 Master/slave interface cable N5102A Digital signal interface module	N7620B	Signal Studio for pulse building
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N7624BSignal Studio for 3GPP LTE-FDDN7625BSignal Studio for 3GPP LTE-TDDN6171AMATLAB softwareCustomized product solutionsE8267D-H1S1 GHz external frequency reference inputE8267D-H1GConnections for phase coherency and improved phase stability < 250 MHzE8267D-H0CConnections for phase coherency > 250 MHz 1E8267D-H18Wideband modulation below 3.2 GHzAccessoriesU3035PDistribution network (lock box) 11819-04278 GByte compact flash memory card8120-8806Master/slave interface cableN5102ADigital signal interface module	N7622A	Signal Studio Toolkit
N7625B Signal Studio for 3GPP LTE-TDD  N6171A MATLAB software  Customized product solutions  E8267D-H1S 1 GHz external frequency reference input  E8267D-H1G Connections for phase coherency and improved phase stability < 250 MHz  E8267D-HCC Connections for phase coherency > 250 MHz 1  E8267D-H18 Wideband modulation below 3.2 GHz  Accessories  U3035P Distribution network (lock box) 1  1819-0427 8 GByte compact flash memory card  8120-8806 Master/slave interface cable  N5102A Digital signal interface module	N7623B	Signal Studio for digital video
N6171A MATLAB software  Customized product solutions  E8267D-H1S 1 GHz external frequency reference input  E8267D-H1G Connections for phase coherency and improved phase stability < 250 MHz  E8267D-HCC Connections for phase coherency > 250 MHz 1  E8267D-H18 Wideband modulation below 3.2 GHz  Accessories  U3035P Distribution network (lock box) 1  1819-0427 8 GByte compact flash memory card  8120-8806 Master/slave interface cable  N5102A Digital signal interface module	N7624B	Signal Studio for 3GPP LTE-FDD
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E8267D-H1G Connections for phase coherency and improved phase stability < 250 MHz  E8267D-HCC Connections for phase coherency > 250 MHz <sup>1</sup> E8267D-H18 Wideband modulation below 3.2 GHz  Accessories  U3035P Distribution network (lock box) <sup>1</sup> 1819-0427 8 GByte compact flash memory card  8120-8806 Master/slave interface cable  N5102A Digital signal interface module	·	1 GHz external frequency reference input
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8120-8806 Master/slave interface cable N5102A Digital signal interface module		· · ·
N5102A Digital signal interface module		
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	N5101A	Baseband Studio PCI card

<sup>1.</sup> Utilized for multiple source phase coherency applications.



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## Related Agilent Literature

Agilent PSG Microwave Signal Generators
Brochure, Literature number 5989-1324EN

E8267D PSG Vector Signal Generator
Configuration Guide, Literature number 5989-1326EN

E8257D PSG Analog Signal Generator

Data Sheet, Literature number 5989-0698EN

Configuration Guide, Literature number 5989-1325EN

E8663D PSG RF Analog Signal Generator
Data Sheet, Literature number 5990-4136EN
Configuration Guide, Literature number 5990-4137EN

PSG Two-tone and Multitone Personalities
Application Note AN 1410, Literature number 5988-7689EN

Signal Studio for Pulse Building

Technical Overview, http://wireless.agilent.com/wireless/helpfiles/n7620a/n7620a.htm

Signal Studio for Multitone Distortion

Technical Overview, http://wireless.agilent.com/wireless/helpfiles/n7621/n7621.htm

Agilent I/Q Modulation Considerations for PSG Vector Signal Generators
Application Note, Literature number 5989-7057EN

Baseband Studio Digital Signal Interface Module
Technical Overview, Literature number 5988-9495EN

Security Features of Agilent Technologies Signal Generators Part Number E4400-90621

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